

# MPC5554 Microcontroller Data Sheet

by: Microcontroller Division

This document provides electrical specifications, pin assignments, and package diagrams for the MPC5554 microcontroller device. For functional characteristics, refer to the *MPC5553/MPC5554 Microcontroller Reference Manual*.

## 1 Overview

The MPC5554 microcontroller (MCU) is a member of the MPC5500 family of microcontrollers built on the Power Architecture™ embedded technology. This family of parts has many new features coupled with high performance CMOS technology to provide substantial reduction of cost per feature and significant performance improvement over the MPC500 family.

The host processor core of this device complies with the Power Architecture embedded category that is 100% user-mode compatible (including floating point library) with the original Power PC™ user instruction set architecture (UISA). The embedded architecture enhancements improve the performance in embedded applications. The core also has additional instructions, including digital signal processing (DSP) instructions, beyond the original Power PC instruction set.

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## Overview

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The MPC5500 family of parts contains many new features coupled with high performance CMOS technology to provide significant performance improvement over the MPC565.

The MPC5554 has two levels of memory hierarchy. The fastest accesses are to the 32-kilobytes (KB) unified cache. The next level in the hierarchy contains the 64-KB on-chip internal SRAM and two-megabytes (MB) internal flash memory. The internal SRAM and flash memory hold instructions and data. The external bus interface is designed to support most of the standard memories used with the MPC5xx family.

The complex input/output timer functions of the MPC5554 are performed by two enhanced time processor unit (eTPU) engines. Each eTPU engine controls 32 hardware channels, providing a total of 64 hardware channels. The eTPU has been enhanced over the TPU by providing: 24-bit timers, double-action hardware channels, variable number of parameters per channel, angle clock hardware, and additional control and arithmetic instructions. The eTPU is programmed using a high-level programming language.

The less complex timer functions of the MPC5554 are performed by the enhanced modular input/output system (eMIOS). The eMIOS' 24 hardware channels are capable of single-action, double-action, pulse-width modulation (PWM), and modulus-counter operations. Motor control capabilities include edge-aligned and center-aligned PWM.

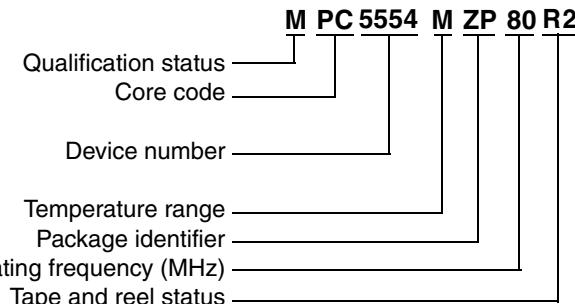
Off-chip communication is performed by a suite of serial protocols including controller area networks (FlexCANs), enhanced deserial/serial peripheral interfaces (DSPIs), and enhanced serial communications interfaces (eSCIs). The DSPIs support pin reduction through hardware serialization and deserialization of timer channels and general-purpose input/output (GPIOs) signals.

The MCU has an on-chip enhanced queued dual analog-to-digital converter (eQADC). The 416 package has 40-channels.

The system integration unit (SIU) performs several chip-wide configuration functions. Pad configuration and general-purpose input and output (GPIO) are controlled from the SIU. External interrupts and reset control are also determined by the SIU. The internal multiplexer submodule (SIU\_DISR) provides multiplexing of eQADC trigger sources, daisy chaining the DSPIs, and external interrupt signal multiplexing.

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## 2 Ordering Information



**Temperature Range**  
 M =  $-40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$   
 A =  $-55^{\circ}\text{C}$  to  $125^{\circ}\text{C}$

**Package Identifier**  
 ZP = 416PBGA SnPb  
 VR = 416PBGA Pb-free

**Operating Frequency**  
 80 = 80 MHz  
 112 = 112 MHz  
 132 = 132 MHz

**Tape and Reel Status**  
 R2 = Tape and reel  
 (blank) = Trays

**Qualification Status**  
 P = Pre qualification  
 M = Fully spec. qualified

**Note:** Not all options are available on all devices. Refer to [Table 1](#).

**Figure 1. MPC5500 Family Part Number Example**

Unless noted in this data sheet, all specifications apply from  $T_L$  to  $T_H$ .

**Table 1. Orderable Part Numbers**

Freescale Part Number <sup>1</sup>	Package Description	Speed (MHz)		Operating Temperature <sup>2</sup>	
		Nominal	Max. <sup>3</sup> ( $f_{MAX}$ )	Min. ( $T_L$ )	Max. ( $T_H$ )
MPC5554MVR132	MPC5554 416 package Lead-free (PbFree)	132	132	$-40^{\circ}\text{C}$	$125^{\circ}\text{C}$
MPC5554MVR112		112	114		
MPC5554MVR80		80	82		
MPC5554AVR132		132	132	$-55^{\circ}\text{C}$	$125^{\circ}\text{C}$
MPC5554MZP132	MPC5554 416 package Leaded (SnPb)	132	132	$-40^{\circ}\text{C}$	$125^{\circ}\text{C}$
MPC5554MZP112		112	114		
MPC5554MZP80		80	82		
MPC5554AZP132		132	132	$-55^{\circ}\text{C}$	$125^{\circ}\text{C}$

<sup>1</sup> All devices are PPC5554, rather than MPC5554, until product qualifications are complete. Not all configurations are available in the PPC parts.

<sup>2</sup> The lowest ambient operating temperature is referenced by  $T_L$ ; the highest ambient operating temperature is referenced by  $T_H$ .

<sup>3</sup> Speed is the nominal maximum frequency. Max. speed is the maximum speed allowed including frequency modulation (FM). 82 MHz parts allow for 80 MHz system clock + 2% FM; 114 MHz parts allow for 112 MHz system clock + 2% FM; and 132 MHz parts allow for 128 MHz system clock + 2% FM.

## Electrical Characteristics

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# 3 Electrical Characteristics

This section contains detailed information on power considerations, DC/AC electrical characteristics, and AC timing specifications for the MCU.

## 3.1 Maximum Ratings

Table 2. Absolute Maximum Ratings <sup>1</sup>

Spec	Characteristic	Symbol	Min.	Max.	Unit
1	1.5 V core supply voltage <sup>2</sup>	$V_{DD}$	-0.3	1.7	V
2	Flash program/erase voltage	$V_{PP}$	-0.3	6.5	V
4	Flash read voltage	$V_{FLASH}$	-0.3	4.6	V
5	SRAM standby voltage	$V_{STBY}$	-0.3	1.7	V
6	Clock synthesizer voltage	$V_{DDSYN}$	-0.3	4.6	V
7	3.3 V I/O buffer voltage	$V_{DD33}$	-0.3	4.6	V
8	Voltage regulator control input voltage	$V_{RC33}$	-0.3	4.6	V
9	Analog supply voltage (reference to $V_{SSA}$ )	$V_{DDA}$	-0.3	5.5	V
10	I/O supply voltage (fast I/O pads) <sup>3</sup>	$V_{DDE}$	-0.3	4.6	V
11	I/O supply voltage (slow and medium I/O pads) <sup>3</sup>	$V_{DDEH}$	-0.3	6.5	V
12	DC input voltage <sup>4</sup> $V_{DDEH}$ powered I/O pads $V_{DDE}$ powered I/O pads	$V_{IN}$	-1.0 <sup>5</sup> -1.0 <sup>5</sup>	6.5 <sup>6</sup> 4.6 <sup>7</sup>	V
13	Analog reference high voltage (reference to $V_{RL}$ )	$V_{RH}$	-0.3	5.5	V
14	$V_{SS}$ to $V_{SSA}$ differential voltage	$V_{SS} - V_{SSA}$	-0.1	0.1	V
15	$V_{DD}$ to $V_{DDA}$ differential voltage	$V_{DD} - V_{DDA}$	- $V_{DDA}$	$V_{DD}$	V
16	$V_{REF}$ differential voltage	$V_{RH} - V_{RL}$	-0.3	5.5	V
17	$V_{RH}$ to $V_{DDA}$ differential voltage	$V_{RH} - V_{DDA}$	-5.5	5.5	V
18	$V_{RL}$ to $V_{SSA}$ differential voltage	$V_{RL} - V_{SSA}$	-0.3	0.3	V
19	$V_{DDEH}$ to $V_{DDA}$ differential voltage	$V_{DDEH} - V_{DDA}$	- $V_{DDA}$	$V_{DDEH}$	V
20	$V_{DDF}$ to $V_{DD}$ differential voltage	$V_{DDF} - V_{DD}$	-0.3	0.3	V
21	$V_{RC33}$ to $V_{DDSYN}$ differential voltage spec has been moved to Table 9 DC Electrical Specifications, Spec 43a.				
22	$V_{SSSYN}$ to $V_{SS}$ differential voltage	$V_{SSSYN} - V_{SS}$	-0.1	0.1	V
23	$V_{RCVSS}$ to $V_{SS}$ differential voltage	$V_{RCVSS} - V_{SS}$	-0.1	0.1	V
24	Maximum DC digital input current <sup>8</sup> (per pin, applies to all digital pins) <sup>4</sup>	$I_{MAXD}$	-2	2	mA
25	Maximum DC analog input current <sup>9</sup> (per pin, applies to all analog pins)	$I_{MAXA}$	-3	3	mA
26	Maximum operating temperature range <sup>10</sup> Die junction temperature	$T_J$	$T_L$	150.0	°C
27	Storage temperature range	$T_{STG}$	-55.0	150.0	°C

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Table 2. Absolute Maximum Ratings<sup>1</sup> (continued)

Spec	Characteristic	Symbol	Min.	Max.	Unit
28	Maximum solder temperature <sup>11</sup> Lead free (Pb-free) Leaded (SnPb)	$T_{SDR}$	—	260.0 245.0	°C
29	Moisture sensitivity level <sup>12</sup>	MSL	—	3	

<sup>1</sup> Functional operating conditions are given in the DC electrical specifications. Absolute maximum ratings are stress ratings only, and functional operation at the maxima is not guaranteed. Stress beyond any of the listed maxima can affect device reliability or cause permanent damage to the device.

<sup>2</sup> 1.5 V ± 10% for proper operation. This parameter is specified at a maximum junction temperature of 150 °C.

<sup>3</sup> All functional non-supply I/O pins are clamped to  $V_{SS}$  and  $V_{DDE}$ , or  $V_{DDEH}$ .

<sup>4</sup> AC signal overshoot and undershoot of up to ± 2.0 V of the input voltages is permitted for an accumulative duration of 60 hours over the complete lifetime of the device (injection current not limited for this duration).

<sup>5</sup> Internal structures hold the voltage greater than -1.0 V if the injection current limit of 2 mA is met. Keep the negative DC voltage greater than -0.6 V on eTPUB[15] and SINB during the internal power-on reset (POR) state.

<sup>6</sup> Internal structures hold the input voltage less than the maximum voltage on all pads powered by  $V_{DDEH}$  supplies, if the maximum injection current specification is met (2 mA for all pins) and  $V_{DDEH}$  is within the operating voltage specifications.

<sup>7</sup> Internal structures hold the input voltage less than the maximum voltage on all pads powered by  $V_{DDE}$  supplies, if the maximum injection current specification is met (2 mA for all pins) and  $V_{DDE}$  is within the operating voltage specifications.

<sup>8</sup> Total injection current for all pins (including both digital and analog) must not exceed 25 mA.

<sup>9</sup> Total injection current for all analog input pins must not exceed 15 mA.

<sup>10</sup> Lifetime operation at these specification limits is not guaranteed.

<sup>11</sup> Moisture sensitivity profile per IPC/JEDEC J-STD-020D.

<sup>12</sup> Moisture sensitivity per JEDEC test method A112.

## 3.2 Thermal Characteristics

The shaded rows in the following table indicate information specific to a four-layer board.

Table 3. MPC5554 Thermal Characteristics

Spec	MPC5554 Thermal Characteristic	Symbol	416 PBGA	Unit
1	Junction to ambient <sup>1, 2</sup> , natural convection (one-layer board)	$R_{\theta JA}$	24	°C/W
2	Junction to ambient <sup>1, 3</sup> , natural convection (four-layer board 2s2p)	$R_{\theta JA}$	18	°C/W
3	Junction to ambient <sup>1, 3</sup> (@200 ft./min., one-layer board)	$R_{\theta JMA}$	19	°C/W
4	Junction to ambient <sup>1, 3</sup> (@200 ft./min., four-layer board 2s2p)	$R_{\theta JMA}$	15	°C/W
5	Junction to board <sup>4</sup> (four-layer board 2s2p)	$R_{\theta JB}$	9	°C/W
6	Junction to case <sup>5</sup>	$R_{\theta JC}$	5	°C/W
7	Junction to package top <sup>6</sup> , natural convection	$\Psi_{JT}$	2	°C/W

<sup>1</sup> Junction temperature is a function of on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, air flow, power dissipation of other components on the board, and board thermal resistance.

<sup>2</sup> Per SEMI G38-87 and JEDEC JESD51-2 with the single-layer board horizontal.

<sup>3</sup> Per JEDEC JESD51-6 with the board horizontal.

<sup>4</sup> Thermal resistance between the die and the printed circuit board per JEDEC JESD51-8. Board temperature is measured on the top surface of the board near the package.

<sup>5</sup> Indicates the average thermal resistance between the die and the case top surface as measured by the cold plate method (MIL SPEC-883 Method 1012.1) with the cold plate temperature used for the case temperature.

<sup>6</sup> Thermal characterization parameter indicating the temperature difference between package top and the junction temperature per JEDEC JESD51-2.

## Electrical Characteristics

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An estimation of the device junction temperature,  $T_J$ , can be obtained from the equation:

$$T_J = T_A + (R_{\theta JA} \times P_D)$$

where:

$T_A$  = ambient temperature for the package ( $^{\circ}\text{C}$ )

$R_{\theta JA}$  = junction to ambient thermal resistance ( $^{\circ}\text{C}/\text{W}$ )

$P_D$  = power dissipation in the package (W)

The thermal resistance values used are based on the JEDEC JESD51 series of standards to provide consistent values for estimations and comparisons. The difference between the values determined for the single-layer (1s) board compared to a four-layer board that has two signal layers, a power and a ground plane (2s2p), demonstrate that the effective thermal resistance is not a constant. The thermal resistance depends on the:

- Construction of the application board (number of planes)
- Effective size of the board which cools the component
- Quality of the thermal and electrical connections to the planes
- Power dissipated by adjacent components

Connect all the ground and power balls to the respective planes with one via per ball. Using fewer vias to connect the package to the planes reduces the thermal performance. Thinner planes also reduce the thermal performance. When the clearance between the vias leave the planes virtually disconnected, the thermal performance is also greatly reduced.

As a general rule, the value obtained on a single-layer board is within the normal range for the tightly packed printed circuit board. The value obtained on a board with the internal planes is usually within the normal range if the application board has:

- One oz. (35 micron nominal thickness) internal planes
- Components are well separated
- Overall power dissipation on the board is less than  $0.02 \text{ W/cm}^2$

The thermal performance of any component depends on the power dissipation of the surrounding components. In addition, the ambient temperature varies widely within the application. For many natural convection and especially closed box applications, the board temperature at the perimeter (edge) of the package is approximately the same as the local air temperature near the device. Specifying the local ambient conditions explicitly as the board temperature provides a more precise description of the local ambient conditions that determine the temperature of the device.

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At a known board temperature, the junction temperature is estimated using the following equation:

$$T_J = T_B + (R_{\theta JB} \times P_D)$$

where:

$T_J$  = junction temperature ( $^{\circ}\text{C}$ )

$T_B$  = board temperature at the package perimeter ( $^{\circ}\text{C}/\text{W}$ )

$R_{\theta JB}$  = junction-to-board thermal resistance ( $^{\circ}\text{C}/\text{W}$ ) per JESD51-8

$P_D$  = power dissipation in the package (W)

When the heat loss from the package case to the air does not factor into the calculation, an acceptable value for the junction temperature is predictable. Ensure the application board is similar to the thermal test condition, with the component soldered to a board with internal planes.

The thermal resistance is expressed as the sum of a junction-to-case thermal resistance plus a case-to-ambient thermal resistance:

$$R_{\theta JA} = R_{\theta JC} + R_{\theta CA}$$

where:

$R_{\theta JA}$  = junction-to-ambient thermal resistance ( $^{\circ}\text{C}/\text{W}$ )

$R_{\theta JC}$  = junction-to-case thermal resistance ( $^{\circ}\text{C}/\text{W}$ )

$R_{\theta CA}$  = case-to-ambient thermal resistance ( $^{\circ}\text{C}/\text{W}$ )

$R_{\theta JC}$  is device related and is not affected by other factors. The thermal environment can be controlled to change the case-to-ambient thermal resistance,  $R_{\theta CA}$ . For example, change the air flow around the device, add a heat sink, change the mounting arrangement on the printed circuit board, or change the thermal dissipation on the printed circuit board surrounding the device. This description is most useful for packages with heat sinks where 90% of the heat flow is through the case to heat sink to ambient. For most packages, a better model is required.

A more accurate two-resistor thermal model can be constructed from the junction-to-board thermal resistance and the junction-to-case thermal resistance. The junction-to-case thermal resistance describes when using a heat sink or where a substantial amount of heat is dissipated from the top of the package. The junction-to-board thermal resistance describes the thermal performance when most of the heat is conducted to the printed circuit board. This model can be used to generate simple estimations and for computational fluid dynamics (CFD) thermal models.

To determine the junction temperature of the device in the application on a prototype board, use the thermal characterization parameter ( $\Psi_{JT}$ ) to determine the junction temperature by measuring the temperature at the top center of the package case using the following equation:

$$T_J = T_T + (\Psi_{JT} \times P_D)$$

where:

$T_T$  = thermocouple temperature on top of the package ( $^{\circ}\text{C}$ )

$\Psi_{JT}$  = thermal characterization parameter ( $^{\circ}\text{C}/\text{W}$ )

$P_D$  = power dissipation in the package (W)

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The thermal characterization parameter is measured in compliance with the JESD51-2 specification using a 40-gauge type T thermocouple epoxied to the top center of the package case. Position the thermocouple so that the thermocouple junction rests on the package. Place a small amount of epoxy on the thermocouple junction and approximately 1 mm of wire extending from the junction. Place the thermocouple wire flat against the package case to avoid measurement errors caused by the cooling effects of the thermocouple wire.

## References:

Semiconductor Equipment and Materials International  
3081 Zanker Rd.  
San Jose, CA., 95134  
(408) 943-6900

MIL-SPEC and EIA/JESD (JEDEC) specifications are available from Global Engineering Documents at 800-854-7179 or 303-397-7956.

JEDEC specifications are available on the web at <http://www.jedec.org>.

1. C.E. Triplett and B. Joiner, "An Experimental Characterization of a 272 PBGA Within an Automotive Engine Controller Module," Proceedings of SemiTherm, San Diego, 1998, pp. 47–54.
2. G. Kromann, S. Shidore, and S. Addison, "Thermal Modeling of a PBGA for Air-Cooled Applications," Electronic Packaging and Production, pp. 53–58, March 1998.
3. B. Joiner and V. Adams, "Measurement and Simulation of Junction to Board Thermal Resistance and Its Application in Thermal Modeling," Proceedings of SemiTherm, San Diego, 1999, pp. 212–220.

## 3.3 Package

The MPC5554 is available in packaged form. Read the package options in [Section 2, "Ordering Information."](#) Refer to [Section 4, "Mechanicals,"](#) for pinouts and package drawings.

## 3.4 EMI (Electromagnetic Interference) Characteristics

Table 4. EMI Testing Specifications <sup>1</sup>

Spec	Characteristic	Minimum	Typical	Maximum	Unit
1	Scan range	0.15	—	1000	MHz
2	Operating frequency	—	—	$f_{MAX}$	MHz
3	$V_{DD}$ operating voltages	—	1.5	—	V
4	$V_{DDSYN}$ , $V_{RC33}$ , $V_{DD33}$ , $V_{FLASH}$ , $V_{DDE}$ operating voltages	—	3.3	—	V
5	$V_{PP}$ , $V_{DDEH}$ , $V_{DDA}$ operating voltages	—	5.0	—	V
6	Maximum amplitude	—	—	$14^2$ $32^3$	dBuV
7	Operating temperature	—	—	25	°C

<sup>1</sup> EMI testing and I/O port waveforms per SAE J1752/3 issued 1995-03. Qualification testing was performed on the MPC5554 and applied to the MPC5500 family as generic EMI performance data.

<sup>2</sup> Measured with the single-chip EMI program.

<sup>3</sup> Measured with the expanded EMI program.

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### 3.5 ESD (Electromagnetic Static Discharge) Characteristics

Table 5. ESD Ratings <sup>1, 2</sup>

Characteristic	Symbol	Value	Unit
ESD for human body model (HBM)		2000	V
HBM circuit description	R1	1500	Ω
	C	100	pF
ESD for field induced charge model (FDCM)		500 (all pins)	V
		750 (corner pins)	
Number of pulses per pin: Positive pulses (HBM) Negative pulses (HBM)	—	1 1	— —
Interval of pulses	—	1	second

<sup>1</sup> All ESD testing conforms to CDF-AEC-Q100 Stress Test Qualification for Automotive Grade Integrated Circuits.

<sup>2</sup> Device failure is defined as: 'If after exposure to ESD pulses, the device does not meet the device specification requirements, which includes the complete DC parametric and functional testing at room temperature and hot temperature.

### 3.6 Voltage Regulator Controller ( $V_{RC}$ ) and Power-On Reset (POR) Electrical Specifications

The following table lists the  $V_{RC}$  and POR electrical specifications:

Table 6.  $V_{RC}$  and POR Electrical Specifications

Spec	Characteristic	Symbol	Min.	Max.	Units
1	1.5 V ( $V_{DD}$ ) POR <sup>1</sup>	$V_{POR15}$	1.1 1.1	1.35 1.35	V
2	3.3 V ( $V_{DDSYN}$ ) POR <sup>1</sup>	$V_{POR33}$	0.0 2.0 2.0 0.0	0.30 2.85 2.85 0.30	V
3	RESET pin supply ( $V_{DDEH6}$ ) POR <sup>1, 2</sup>	$V_{POR5}$	2.0 2.0	2.85 2.85	V
4	$V_{RC33}$ voltage	Before $V_{RC}$ allows the pass transistor to start turning on	$V_{TRANS\_START}$	1.0	2.0
5		When $V_{RC}$ allows the pass transistor to completely turn on <sup>3, 4</sup>	$V_{TRANS\_ON}$	2.0	2.85
6		When the voltage is greater than the voltage at which the $V_{RC}$ keeps the 1.5 V supply in regulation <sup>5, 6</sup>	$V_{VRC33REG}$	3.0	—
		−55° C <sup>7</sup>		11.0	—
7	Current can be sourced by $V_{RCCTL}$ at $T_j$ :	$I_{VRCCTL}$ <sup>8</sup>	11.0 9.0 7.5	— — —	mA
		−40° C 25° C 150° C			

## Electrical Characteristics

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Table 6.  $V_{RC}$  and POR Electrical Specifications (continued)

Spec	Characteristic	Symbol	Min.	Max.	Units
8	Voltage differential during power up such that: $V_{DD33}$ can lag $V_{DDSYN}$ or $V_{DDEH6}$ before $V_{DDSYN}$ and $V_{DDEH6}$ reach the $V_{POR33}$ and $V_{POR5}$ minimums respectively.	$V_{DD33\_LAG}$	—	1.0	V
9	Absolute value of slew rate on power supply pins	—	—	50	V/ms
10	Required gain at $T_j$ : $I_{DD} \div I_{VRCCTL}$ (@ $f_{sys} = f_{MAX}$ ) <sup>6, 8, 9, 10</sup>	$-55^\circ C$ $-40^\circ C$ $25^\circ C$ $150^\circ C$	BETA <sup>11</sup>	70 70 85 <sup>11</sup> 105 <sup>11</sup>	— — — 500

<sup>1</sup> The internal POR signals are  $V_{POR15}$ ,  $V_{POR33}$ , and  $V_{POR5}$ . On power up, assert  $\overline{RESET}$  before the internal POR negates.  $\overline{RESET}$  must remain asserted until the power supplies are within the operating conditions as specified in Table 9 DC Electrical Specifications. On power down, assert  $\overline{RESET}$  before any power supplies fall outside the operating conditions and until the internal POR asserts.

<sup>2</sup>  $V_{IL\_S}$  (Table 9, Spec15) is guaranteed to scale with  $V_{DDEH6}$  down to  $V_{POR5}$ .

<sup>3</sup> Supply full operating current for the 1.5 V supply when the 3.3 V supply reaches this range.

<sup>4</sup> It is possible to reach the current limit during ramp up—do not treat this event as short circuit current.

<sup>5</sup> At peak current for device.

<sup>6</sup> Requires compliance with Freescale's recommended board requirements and transistor recommendations. Board signal traces/routing from the  $V_{RCCTL}$  package signal to the base of the external pass transistor and between the emitter of the pass transistor to the  $V_{DD}$  package signals must have a maximum of 100 nH inductance and minimal resistance (less than 1  $\Omega$ ).  $V_{RCCTL}$  must have a nominal 1  $\mu F$  phase compensation capacitor to ground.  $V_{DD}$  must have a 20  $\mu F$  (nominal) bulk capacitor (greater than 4  $\mu F$  over all conditions, including lifetime). Place high-frequency bypass capacitors consisting of eight 0.01  $\mu F$ , two 0.1  $\mu F$ , and one 1  $\mu F$  capacitors around the package on the  $V_{DD}$  supply signals.

<sup>7</sup> Only available on devices that support  $-55^\circ C$ .

<sup>8</sup>  $I_{VRCCTL}$  is measured at the following conditions:  $V_{DD} = 1.35$  V,  $V_{RC33} = 3.1$  V,  $V_{VRCCTL} = 2.2$  V.

<sup>9</sup> Refer to Table 1 for the maximum operating frequency.

<sup>10</sup> Values are based on  $I_{DD}$  from high-use applications as explained in the  $I_{DD}$  Electrical Specification.

<sup>11</sup> BETA represents the worst-case external transistor. It is measured on a per-part basis and calculated as  $(I_{DD} \div I_{VRCCTL})$ .

## 3.7 Power-Up/Down Sequencing

Power sequencing between the 1.5 V power supply and  $V_{DDSYN}$  or the  $\overline{RESET}$  power supplies is required if using an external 1.5 V power supply with  $V_{RC33}$  tied to ground (GND). To avoid power-sequencing,  $V_{RC33}$  must be powered up within the specified operating range, even if the on-chip voltage regulator controller is not used. Refer to Section 3.7.2, “Power-Up Sequence (VRC33 Grounded),” and Section 3.7.3, “Power-Down Sequence (VRC33 Grounded).”

Power sequencing requires that  $V_{DD33}$  must reach a certain voltage where the values are read as ones before the POR signal negates. Refer to Section 3.7.1, “Input Value of Pins During POR Dependent on  $VDD33$ .”

Although power sequencing is not required between  $V_{RC33}$  and  $V_{DDSYN}$  during power up,  $V_{RC33}$  must not lead  $V_{DDSYN}$  by more than 600 mV or lag by more than 100 mV for the  $V_{RC}$  stage turn-on to operate within specification. Higher spikes in the emitter current of the pass transistor occur if  $V_{RC33}$  leads or lags  $V_{DDSYN}$  by more than these amounts. The value of that higher spike in current depends on the board power supply circuitry and the amount of board level capacitance.

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Furthermore, when all of the PORs negate, the system clock starts to toggle, adding another large increase of the current consumed by  $V_{RC33}$ . If  $V_{RC33}$  lags  $V_{DDSYN}$  by more than 100 mV, the increase in current consumed can drop  $V_{DD}$  low enough to assert the 1.5 V POR again. Oscillations are possible when the 1.5 V POR asserts and stops the system clock, causing the voltage on  $V_{DD}$  to rise until the 1.5 V POR negates again. All oscillations stop when  $V_{RC33}$  is powered sufficiently.

When powering down,  $V_{RC33}$  and  $V_{DDSYN}$  have no delta requirement to each other, because the bypass capacitors internal and external to the device are already charged. When not powering up or down, no delta between  $V_{RC33}$  and  $V_{DDSYN}$  is required for the  $V_{RC}$  to operate within specification.

There are no power up/down sequencing requirements to prevent issues such as latch-up, excessive current spikes, and so on. Therefore, the state of the I/O pins during power up and power down varies depending on which supplies are powered.

**Table 7** gives the pin state for the sequence cases for all pins with pad type pad\_fc (fast type).

**Table 7. Pin Status for Fast Pads During the Power Sequence**

$V_{DDE}$	$V_{DD33}$	$V_{DD}$	POR	Pin Status for Fast Pad Output Driver pad_fc (fast)
Low	—	—	Asserted	Low
$V_{DDE}$	Low	Low	Asserted	High
$V_{DDE}$	Low	$V_{DD}$	Asserted	High
$V_{DDE}$	$V_{DD33}$	Low	Asserted	High impedance (Hi-Z)
$V_{DDE}$	$V_{DD33}$	$V_{DD}$	Asserted	Hi-Z
$V_{DDE}$	$V_{DD33}$	$V_{DD}$	Negated	Functional

**Table 8** gives the pin state for the sequence cases for all pins with pad type pad\_mh (medium type) and pad\_sh (slow type).

**Table 8. Pin Status for Medium and Slow Pads During the Power Sequence**

$V_{DDEH}$	$V_{DD}$	POR	Pin Status for Medium and Slow Pad Output Driver pad_mh (medium) pad_sh (slow)
Low	—	Asserted	Low
$V_{DDEH}$	Low	Asserted	High impedance (Hi-Z)
$V_{DDEH}$	$V_{DD}$	Asserted	Hi-Z
$V_{DDEH}$	$V_{DD}$	Negated	Functional

The values in **Table 7** and **Table 8** do not include the effect of the weak-pull devices on the output pins during power up.

Before exiting the internal POR state, the pins go to a high-impedance state until POR negates. When the internal POR negates, the functional state of the signal during reset applies and the weak-pull devices (up or down) are enabled as defined in the device reference manual. If  $V_{DD}$  is too low to correctly propagate the logic signals, the weak-pull devices can pull the signals to  $V_{DDE}$  and  $V_{DDEH}$ .

To avoid this condition, minimize the ramp time of the  $V_{DD}$  supply to a time period less than the time required to enable the external circuitry connected to the device outputs.

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### 3.7.1 Input Value of Pins During POR Dependent on $V_{DD33}$

When powering up the device,  $V_{DD33}$  must not lag the latest  $V_{DDSYN}$  or  $\overline{\text{RESET}}$  power pin ( $V_{DDEH6}$ ) by more than the  $V_{DD33}$  lag specification listed in [Table 6](#), spec 8. This avoids accidentally selecting the bypass clock mode because the internal versions of  $\text{PLLCFG}[0:1]$  and  $\text{RSTCFG}$  are not powered and therefore cannot read the default state when POR negates.  $V_{DD33}$  can lag  $V_{DDSYN}$  or the  $\overline{\text{RESET}}$  power pin ( $V_{DDEH6}$ ), but cannot lag both by more than the  $V_{DD33}$  lag specification. This  $V_{DD33}$  lag specification applies during power up only.  $V_{DD33}$  has no lead or lag requirements when powering down.

### 3.7.2 Power-Up Sequence ( $V_{RC33}$ Grounded)

The 1.5 V  $V_{DD}$  power supply must rise to 1.35 V before the 3.3 V  $V_{DDSYN}$  power supply and the  $\overline{\text{RESET}}$  power supply rises above 2.0 V. This ensures that digital logic in the PLL for the 1.5 V power supply does not begin to operate below the specified operation range lower limit of 1.35 V. Because the internal 1.5 V POR is disabled, the internal 3.3 V POR or the  $\overline{\text{RESET}}$  power POR must hold the device in reset. Since they can negate as low as 2.0 V,  $V_{DD}$  must be within specification before the 3.3 V POR and the  $\overline{\text{RESET}}$  POR negate.

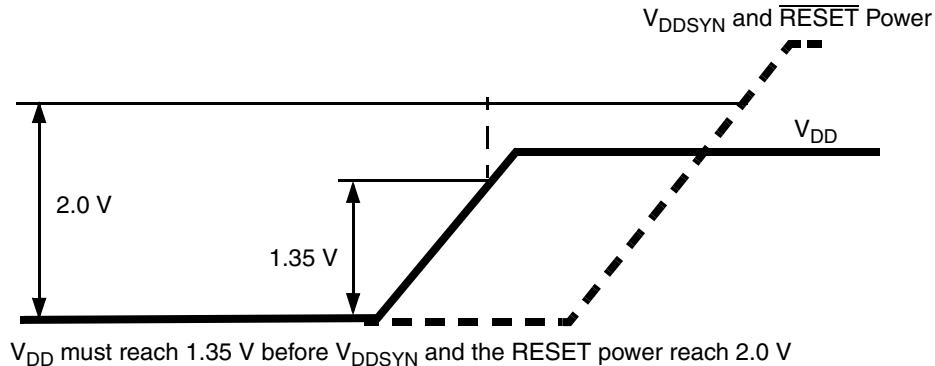


Figure 2. Power-Up Sequence ( $V_{RC33}$  Grounded)

### 3.7.3 Power-Down Sequence ( $V_{RC33}$ Grounded)

The only requirement for the power-down sequence with  $V_{RC33}$  grounded is if  $V_{DD}$  decreases to less than its operating range,  $V_{DDSYN}$  or the  $\overline{\text{RESET}}$  power must decrease to less than 2.0 V before the  $V_{DD}$  power increases to its operating range. This ensures that the digital 1.5 V logic, which is reset only by an ORed POR and can cause the 1.5 V supply to decrease less than its specification value, resets correctly. See [Table 6](#), footnote 1.

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### 3.8 DC Electrical Specifications

Table 9. DC Electrical Specifications ( $T_A = T_L$  to  $T_H$ )

Spec	Characteristic	Symbol	Min	Max.	Unit
1	Core supply voltage (average DC RMS voltage)	$V_{DD}$	1.35	1.65	V
2	Input/output supply voltage (fast input/output) <sup>1</sup>	$V_{DDE}$	1.62	3.6	V
3	Input/output supply voltage (slow and medium input/output)	$V_{DDEH}$	3.0	5.25	V
4	3.3 V input/output buffer voltage	$V_{DD33}$	3.0	3.6	V
5	Voltage regulator control input voltage	$V_{RC33}$	3.0	3.6	V
6	Analog supply voltage <sup>2</sup>	$V_{DDA}$	4.5	5.25	V
8	Flash programming voltage <sup>3</sup>	$V_{PP}$	4.5	5.25	V
9	Flash read voltage	$V_{FLASH}$	3.0	3.6	V
10	SRAM standby voltage <sup>4</sup>	$V_{STBY}$	0.8	1.2	V
11	Clock synthesizer operating voltage	$V_{DDSYN}$	3.0	3.6	V
12	Fast I/O input high voltage	$V_{IH\_F}$	$0.65 \times V_{DDE}$	$V_{DDE} + 0.3$	V
13	Fast I/O input low voltage	$V_{IL\_F}$	$V_{SS} - 0.3$	$0.35 \times V_{DDE}$	V
14	Medium and slow I/O input high voltage	$V_{IH\_S}$	$0.65 \times V_{DDEH}$	$V_{DDEH} + 0.3$	V
15	Medium and slow I/O input low voltage	$V_{IL\_S}$	$V_{SS} - 0.3$	$0.35 \times V_{DDEH}$	V
16	Fast input hysteresis	$V_{HYS\_F}$	$0.1 \times V_{DDE}$		V
17	Medium and slow I/O input hysteresis	$V_{HYS\_S}$	$0.1 \times V_{DDEH}$		V
18	Analog input voltage	$V_{INDC}$	$V_{SSA} - 0.3$	$V_{DDA} + 0.3$	V
19	Fast output high voltage ( $I_{OH\_F} = -2.0$ mA)	$V_{OH\_F}$	$0.8 \times V_{DDE}$	—	V
20	Slow and medium output high voltage $I_{OH\_S} = -2.0$ mA $I_{OH\_S} = -1.0$ mA	$V_{OH\_S}$	$0.80 \times V_{DDEH}$ $0.85 \times V_{DDEH}$	—	V
21	Fast output low voltage ( $I_{OL\_F} = 2.0$ mA)	$V_{OL\_F}$	—	$0.2 \times V_{DDE}$	V
22	Slow and medium output low voltage $I_{OL\_S} = 2.0$ mA $I_{OL\_S} = 1.0$ mA	$V_{OL\_S}$	—	$0.20 \times V_{DDEH}$ $0.15 \times V_{DDEH}$	V
23	Load capacitance (fast I/O) <sup>5</sup> DSC (SIU_PCR[8:9]) = 0b00 = 0b01 = 0b10 = 0b11	$C_L$	— — — —	10 20 30 50	pF
24	Input capacitance (digital pins)	$C_{IN}$	—	7	pF
25	Input capacitance (analog pins)	$C_{IN\_A}$	—	10	pF
26	Input capacitance: (Shared digital and analog pins AN[12]_MA[0]_SDS, AN[13]_MA[1]_SDO, AN[14]_MA[2]_SDI, and AN[15]_FCK)	$C_{IN\_M}$	—	12	pF

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Table 9. DC Electrical Specifications ( $T_A = T_L$  to  $T_H$ ) (continued)

Spec	Characteristic	Symbol	Min	Max.	Unit
27a	Operating Current 1.5 V Supplies @ 132 MHz: <sup>6, 7</sup>  $V_{DD}$ (including $V_{DDF}$ max current) @ 1.65 V typical use <sup>8, 9</sup> $V_{DD}$ (including $V_{DDF}$ max current) @ 1.4 V typical use <sup>8, 9</sup> $V_{DD}$ (including $V_{DDF}$ max current) @ 1.65 V high use <sup>9, 10</sup> $V_{DD}$ (including $V_{DDF}$ max current) @ 1.4 V high use <sup>9, 10</sup>	$I_{DD}$ $I_{DD}$ $I_{DD}$ $I_{DD}$	— — — —	700 600 875 740	mA mA mA mA
27b	Operating Current 1.5 V Supplies @ 114 MHz: <sup>6, 7</sup>  $V_{DD}$ (including $V_{DDF}$ max current) @ 1.65 V typical use <sup>8, 9</sup> $V_{DD}$ (including $V_{DDF}$ max current) @ 1.4 V typical use <sup>8, 9</sup> $V_{DD}$ (including $V_{DDF}$ max current) @ 1.65 V high use <sup>9, 10</sup> $V_{DD}$ (including $V_{DDF}$ max current) @ 1.4 V high use <sup>9, 10</sup>	$I_{DD}$ $I_{DD}$ $I_{DD}$ $I_{DD}$	— — — —	609 522 760 643	mA mA mA mA
27c	Operating Current 1.5 V Supplies @ 82 MHz: <sup>6, 7</sup>  $V_{DD}$ (including $V_{DDF}$ max current) @ 1.65 V typical use <sup>8, 9</sup> $V_{DD}$ (including $V_{DDF}$ max current) @ 1.40 V typical use <sup>8, 9</sup> $V_{DD}$ (including $V_{DDF}$ max current) @ 1.65 V high use <sup>9, 10</sup> $V_{DD}$ (including $V_{DDF}$ max current) @ 1.40 V high use <sup>9, 10</sup>	$I_{DD}$ $I_{DD}$ $I_{DD}$ $I_{DD}$	— — — —	446 384 555 471	mA mA mA mA
27d	Refer to Figure 3 for an interpolation of this data. <sup>11</sup>  $I_{DD\_STBY}$ @ 25°C $V_{STBY}$ @ 0.8 V $V_{STBY}$ @ 1.0 V $V_{STBY}$ @ 1.2 V  $I_{DD\_STBY}$ @ 60°C $V_{STBY}$ @ 0.8 V $V_{STBY}$ @ 1.0 V $V_{STBY}$ @ 1.2 V  $I_{DD\_STBY}$ @ 150°C ( $T_j$ ) $V_{STBY}$ @ 0.8 V $V_{STBY}$ @ 1.0 V $V_{STBY}$ @ 1.2 V	$I_{DD\_STBY}$ $I_{DD\_STBY}$ $I_{DD\_STBY}$  $I_{DD\_STBY}$ $I_{DD\_STBY}$ $I_{DD\_STBY}$  $I_{DD\_STBY}$ $I_{DD\_STBY}$ $I_{DD\_STBY}$	— — —  — — —  — — —	20 30 50  70 100 200  1200 1500 2000	$\mu A$ $\mu A$ $\mu A$  $\mu A$ $\mu A$ $\mu A$  $\mu A$ $\mu A$ $\mu A$
28	Operating current 3.3 V supplies @ $f_{MAX}$ MHz  $V_{DD33}$ <sup>12</sup>  $V_{FLASH}$ $V_{DDSYN}$	$I_{DD\_33}$  $I_{VFLASH}$ $I_{DDSYN}$	— — —	2 + (values derived from procedure of footnote <sup>12</sup> )	mA mA mA
29	Operating current 5.0 V supplies (12 MHz ADCLK): $V_{DDA}$ ( $V_{DDA0} + V_{DDA1}$ ) Analog reference supply current ( $V_{RH}$ , $V_{RL}$ ) $V_{PP}$	$I_{DD\_A}$ $I_{REF}$ $I_{PP}$	— — —	20.0 1.0 25.0	mA mA mA

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Table 9. DC Electrical Specifications ( $T_A = T_L$  to  $T_H$ ) (continued)

Spec	Characteristic	Symbol	Min	Max.	Unit
30	Operating current $V_{DDE}$ supplies: <sup>13</sup> $V_{DDE1}$ $V_{DDE2}$ $V_{DDE3}$ $V_{DDE4}$ $V_{DDE5}$ $V_{DDE6}$ $V_{DDE7}$ $V_{DDE8}$ $V_{DDE9}$	$I_{DD1}$ $I_{DD2}$ $I_{DD3}$ $I_{DD4}$ $I_{DD5}$ $I_{DD6}$ $I_{DD7}$ $I_{DD8}$ $I_{DD9}$	— — — — — — — — —	Refer to Footnote <sup>13</sup>	mA mA mA mA mA mA mA mA mA
31	Fast I/O weak pullup current <sup>14</sup> 1.62–1.98 V 2.25–2.75 V 3.00–3.60 V	$I_{ACT\_F}$	10 20 20	110 130 170	$\mu$ A $\mu$ A $\mu$ A
	Fast I/O weak pulldown current <sup>14</sup> 1.62–1.98 V 2.25–2.75 V 3.00–3.60 V		10 20 20	100 130 170	$\mu$ A $\mu$ A $\mu$ A
32	Slow and medium I/O weak pullup/down current <sup>14</sup> 3.0–3.6 V 4.5–5.5 V	$I_{ACT\_S}$	10 20	150 170	$\mu$ A $\mu$ A
33	I/O input leakage current <sup>15</sup>	$I_{INACT\_D}$	—2.5	2.5	$\mu$ A
34	DC injection current (per pin)	$I_{IC}$	—2.0	2.0	mA
35	Analog input current, channel off <sup>16</sup>	$I_{INACT\_A}$	—150	150	nA
35a	Analog input current, shared analog / digital pins (AN[12], AN[13], AN[14], AN[15])	$I_{INACT\_AD}$	—2.5	2.5	$\mu$ A
36	$V_{SS}$ to $V_{SSA}$ differential voltage <sup>17</sup>	$V_{SS} - V_{SSA}$	—100	100	mV
37	Analog reference low voltage	$V_{RL}$	$V_{SSA} - 0.1$	$V_{SSA} + 0.1$	V
38	$V_{RL}$ differential voltage	$V_{RL} - V_{SSA}$	—100	100	mV
39	Analog reference high voltage	$V_{RH}$	$V_{DDA} - 0.1$	$V_{DDA} + 0.1$	V
40	$V_{REF}$ differential voltage	$V_{RH} - V_{RL}$	4.5	5.25	V
41	$V_{SSSYN}$ to $V_{SS}$ differential voltage	$V_{SSSYN} - V_{SS}$	—50	50	mV
42	$V_{RCVSS}$ to $V_{SS}$ differential voltage	$V_{RCVSS} - V_{SS}$	—50	50	mV
43	$V_{DDF}$ to $V_{DD}$ differential voltage	$V_{DDF} - V_{DD}$	—100	100	mV
43a	$V_{RC33}$ to $V_{DDSYN}$ differential voltage	$V_{RC33} - V_{DDSYN}$	—0.1	0.1 <sup>18</sup>	V
44	Analog input differential signal range (with common mode 2.5 V)	$V_{IDIFF}$	—2.5	2.5	V
45	Operating temperature range, ambient (packaged)	$T_A = (T_L$ to $T_H)$	$T_L$	$T_H$	°C
46	Slew rate on power-supply pins	—	—	50	V/ms

<sup>1</sup>  $V_{DDE2}$  and  $V_{DDE3}$  are limited to 2.25–3.6 V only if SIU\_ECCR[EBTS] = 0;  $V_{DDE2}$  and  $V_{DDE3}$  have a range of 1.6–3.6 V if SIU\_ECCR[EBTS] = 1.

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[2](#)  $|V_{DDA0} - V_{DDA1}|$  must be  $> 0.1$  V.

[3](#)  $V_{PP}$  can drop to 3.0 V during read operations.

[4](#) If standby operation is not required, connect  $V_{STBY}$  to ground.

[5](#) Applies to CLKOUT, external bus pins, and Nexus pins.

[6](#) Maximum average RMS DC current.

[7](#) [Figure 3](#) shows an illustration of the  $I_{DD\_STBY}$  values interpolated for these temperature values.

[8](#) Average current measured on automotive benchmark.

[9](#) Peak currents can be higher on specialized code.

[10](#) High use current measured while running optimized SPE assembly code with all code and data 100% locked in cache (0% miss rate) with all channels of the eMIOS and eTPU running autonomously, plus the eDMA transferring data continuously from SRAM to SRAM. Higher currents are possible if an “idle” loop that crosses cache lines is run from cache. Write code that avoids this condition.

[11](#) [Figure 3](#) shows an illustration of the  $I_{DD\_STBY}$  values interpolated for these temperature values.

[12](#) Power requirements for the  $V_{DD33}$  supply depend on the frequency of operation, load of all I/O pins, and the voltages on the I/O segments. Refer to [Table 11](#) for values to calculate the power dissipation for a specific operation.

[13](#) Power requirements for each I/O segment are dependent on the frequency of operation and load of the I/O pins on a particular I/O segment, and the voltage of the I/O segment. Refer to [Table 10](#) for values to calculate power dissipation for specific operation. The total power consumption of an I/O segment is the sum of the individual power consumptions for each pin on the segment.

[14](#) Absolute value of current, measured at  $V_{IL}$  and  $V_{IH}$ .

[15](#) Weak pullup/down inactive. Measured at  $V_{DDE} = 3.6$  V and  $V_{DDEH} = 5.25$  V. Applies to pad types: pad\_fc, pad\_sh, and pad\_mh.

[16](#) Maximum leakage occurs at maximum operating temperature. Leakage current decreases by approximately one-half for each 8 °C to 12 °C, in the ambient temperature range of 50 °C to 125 °C. Applies to pad types: pad\_a and pad\_ae.

[17](#)  $V_{SSA}$  refers to both  $V_{SSA0}$  and  $V_{SSA1}$ .  $|V_{SSA0} - V_{SSA1}|$  must be  $< 0.1$  V.

[18](#) Up to 0.6 V during power up and power down.

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Figure 3 shows an approximate interpolation of the  $I_{STBY}$  worst-case specification to estimate values at different voltages and temperatures. The vertical lines shown at 25 °C, 60 °C, and 150 °C in Figure 3 are the actual  $I_{DD\_STBY}$  specifications (27d) listed in Table 9.

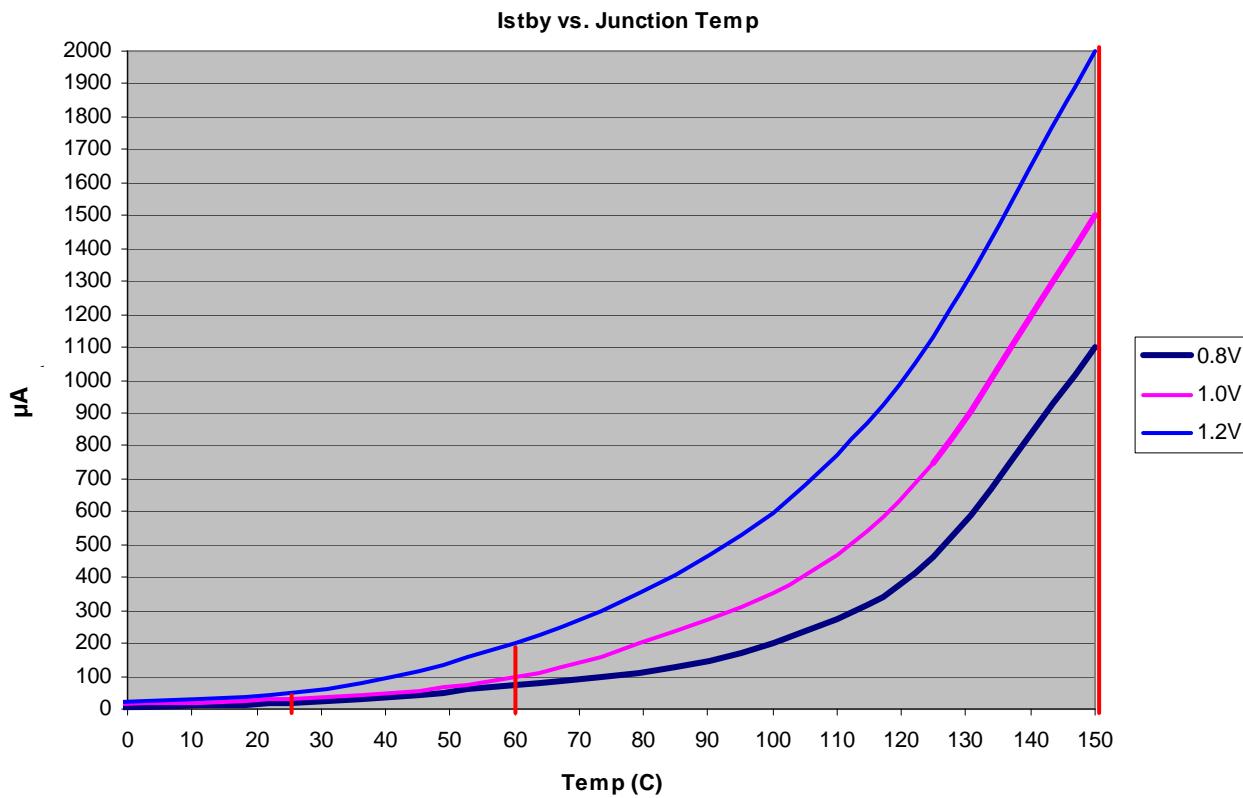


Figure 3.  $I_{STBY}$  Worst-case Specifications

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### 3.8.1 I/O Pad Current Specifications

The power consumption of an I/O segment depends on the usage of the pins on a particular segment. The power consumption is the sum of all output pin currents for a segment. The output pin current can be calculated from [Table 10](#) based on the voltage, frequency, and load on the pin. Use linear scaling to calculate pin currents for voltage, frequency, and load parameters that fall outside the values given in [Table 10](#).

**Table 10. I/O Pad Average DC Current ( $T_A = T_L$  to  $T_H$ )<sup>1</sup>**

Spec	Pad Type	Symbol	Frequency (MHz)	Load <sup>2</sup> (pF)	Voltage (V)	Drive Select / Slew Rate Control Setting	Current (mA)
1	Slow	$I_{DRV\_SH}$	25	50	5.25	11	8.0
2			10	50	5.25	01	3.2
3			2	50	5.25	00	0.7
4			2	200	5.25	00	2.4
5	Medium	$I_{DRV\_MH}$	50	50	5.25	11	17.3
6			20	50	5.25	01	6.5
7			3.33	50	5.25	00	1.1
8			3.33	200	5.25	00	3.9
9	Fast	$I_{DRV\_FC}$	66	10	3.6	00	2.8
10			66	20	3.6	01	5.2
11			66	30	3.6	10	8.5
12			66	50	3.6	11	11.0
13			66	10	1.98	00	1.6
14			66	20	1.98	01	2.9
15			66	30	1.98	10	4.2
16			66	50	1.98	11	6.7
17			56	10	3.6	00	2.4
18			56	20	3.6	01	4.4
19			56	30	3.6	10	7.2
20			56	50	3.6	11	9.3
21			56	10	1.98	00	1.3
22			56	20	1.98	01	2.5
23			56	30	1.98	10	3.5
24			56	50	1.98	11	5.7
25			40	10	3.6	00	1.7
26			40	20	3.6	01	3.1
27			40	30	3.6	10	5.1
28			40	50	3.6	11	6.6
29			40	10	1.98	00	1.0
30			40	20	1.98	01	1.8
31			40	30	1.98	10	2.5
32			40	50	1.98	11	4.0

<sup>1</sup> These values are estimates from simulation and are not tested. Currents apply to output pins only.

<sup>2</sup> All loads are lumped.

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### 3.8.2 I/O Pad V<sub>DD33</sub> Current Specifications

The power consumption of the V<sub>DD33</sub> supply depends on the usage of the pins on all I/O segments. The power consumption is the sum of all input and output pin V<sub>DD33</sub> currents for all I/O segments. The output pin V<sub>DD33</sub> current can be calculated from [Table 11](#) based on the voltage, frequency, and load on all fast (pad\_fc) pins. The input pin V<sub>DD33</sub> current can be calculated from [Table 11](#) based on the voltage, frequency, and load on all pad\_sh and pad\_mh pins. Use linear scaling to calculate pin currents for voltage, frequency, and load parameters that fall outside the values given in [Table 11](#).

**Table 11. V<sub>DD33</sub> Pad Average DC Current (T<sub>A</sub> = T<sub>L</sub> to T<sub>H</sub>)<sup>1</sup>**

Spec	Pad Type	Symbol	Frequency (MHz)	Load <sup>2</sup> (pF)	V <sub>DD33</sub> (V)	V <sub>DDE</sub> (V)	Drive Select	Current (mA)
<b>Inputs</b>								
1	Slow	I <sub>33_SH</sub>	66	0.5	3.6	5.5	NA	0.003
2	Medium	I <sub>33_MH</sub>	66	0.5	3.6	5.5	NA	0.003
<b>Outputs</b>								
3	Fast	I <sub>33_FC</sub>	66	10	3.6	3.6	00	0.35
4			66	20	3.6	3.6	01	0.53
5			66	30	3.6	3.6	10	0.62
6			66	50	3.6	3.6	11	0.79
7			66	10	3.6	1.98	00	0.35
8			66	20	3.6	1.98	01	0.44
9			66	30	3.6	1.98	10	0.53
10			66	50	3.6	1.98	11	0.70
11			56	10	3.6	3.6	00	0.30
12			56	20	3.6	3.6	01	0.45
13			56	30	3.6	3.6	10	0.52
14			56	50	3.6	3.6	11	0.67
15			56	10	3.6	1.98	00	0.30
16			56	20	3.6	1.98	01	0.37
17			56	30	3.6	1.98	10	0.45
18			56	50	3.6	1.98	11	0.60
19			40	10	3.6	3.6	00	0.21
20			40	20	3.6	3.6	01	0.31
21			40	30	3.6	3.6	10	0.37
22			40	50	3.6	3.6	11	0.48
23			40	10	3.6	1.98	00	0.21
24			40	20	3.6	1.98	01	0.27
25			40	30	3.6	1.98	10	0.32
26			40	50	3.6	1.98	11	0.42

<sup>1</sup> These values are estimated from simulation and not tested. Currents apply to output pins for the fast pads only and to input pins for the slow and medium pads only.

<sup>2</sup> All loads are lumped.

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### 3.9 Oscillator and FMPLL Electrical Characteristics

Table 12. FMPLL Electrical Specifications

( $V_{DDSYN} = 3.0\text{--}3.6\text{ V}$ ;  $V_{SS} = V_{SSSYN} = 0.0\text{ V}$ ;  $T_A = T_L$  to  $T_H$ )

Spec	Characteristic	Symbol	Minimum	Maximum	Unit
1	PLL reference frequency range: <sup>1</sup> Crystal reference External reference Dual controller (1:1 mode)	$f_{ref\_crystal}$ $f_{ref\_ext}$ $f_{ref\_1:1}$	8 8 24	20 20 $f_{sys} \div 2$	MHz
2	System frequency <sup>2</sup>	$f_{sys}$	$f_{ICO(MIN)} \div 2^{RFD}$	$f_{MAX}^3$	MHz
3	System clock period	$t_{CYC}$	—	$1 \div f_{sys}$	ns
4	Loss of reference frequency <sup>4</sup>	$f_{LOR}$	100	1000	kHz
5	Self-clocked mode (SCM) frequency <sup>5</sup>	$f_{SCM}$	7.4	17.5	MHz
6	EXTAL input high voltage crystal mode <sup>6</sup> All other modes [dual controller (1:1), bypass, external reference]	$V_{IHEXT}$ $V_{IHEXT}$	$V_{XTAL} + 0.4\text{ V}$ $(V_{DDE5} \div 2) + 0.4\text{ V}$	— —	V
7	EXTAL input low voltage crystal mode <sup>7</sup> All other modes [dual controller (1:1), bypass, external reference]	$V_{ILEXT}$ $V_{ILEXT}$	— —	$V_{XTAL} - 0.4\text{ V}$ $(V_{DDE5} \div 2) - 0.4\text{ V}$	V
8	XTAL current <sup>8</sup>	$I_{XTAL}$	0.8	3	mA
9	Total on-chip stray capacitance on XTAL	$C_{S\_XTAL}$	—	1.5	pF
10	Total on-chip stray capacitance on EXTAL	$C_{S\_EXTAL}$	—	1.5	pF
11	Crystal manufacturer's recommended capacitive load	$C_L$	Refer to crystal specification	Refer to crystal specification	pF
12	Discrete load capacitance to connect to EXTAL	$C_{L\_EXTAL}$	—	$(2 \times C_L) - C_{S\_EXTAL}^9$ $- C_{PCB\_EXTAL}$	pF
13	Discrete load capacitance to connect to XTAL	$C_{L\_XTAL}$	—	$(2 \times C_L) - C_{S\_XTAL}^9$ $- C_{PCB\_XTAL}$	pF
14	PLL lock time <sup>10</sup>	$t_{PLL}$	—	750	$\mu\text{s}$
15	Dual controller (1:1) clock skew (between CLKOUT and EXTAL) <sup>11, 12</sup>	$t_{skew}$	-2	2	ns
16	Duty cycle of reference	$t_{DC}$	40	60	%
17	Frequency unLOCK range	$f_{UL}$	-4.0	4.0	% $f_{sys}$
18	Frequency LOCK range	$f_{LCK}$	-2.0	2.0	% $f_{sys}$

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Table 12. FMPLL Electrical Specifications (continued)

(V<sub>DDSYN</sub> = 3.0–3.6 V; V<sub>SS</sub> = V<sub>SSSYN</sub> = 0.0 V; T<sub>A</sub> = T<sub>L</sub> to T<sub>H</sub>)

Spec	Characteristic	Symbol	Minimum	Maximum	Unit
19	CLKOUT period jitter, measured at f <sub>SYS</sub> max: <sup>13, 14</sup> Peak-to-peak jitter (clock edge to clock edge) Long term jitter (averaged over a 2 ms interval)	C <sub>JITTER</sub>	—	5.0 0.01	% f <sub>CLKOUT</sub>
20	Frequency modulation range limit <sup>15</sup> (do not exceed f <sub>sys</sub> maximum)	C <sub>MOD</sub>	0.8	2.4	%f <sub>SYS</sub>
21	ICO frequency f <sub>ico</sub> = [ f <sub>ref_crystal</sub> × (MFD + 4) ] ÷ (PREDIV + 1) <sup>16</sup> f <sub>ico</sub> = [ f <sub>ref_ext</sub> × (MFD + 4) ] ÷ (PREDIV + 1)	f <sub>ico</sub>	48	f <sub>MAX</sub>	MHz
22	Predivider output frequency (to PLL)	f <sub>PREDIV</sub>	4	20 <sup>17</sup>	MHz

<sup>1</sup> Nominal crystal and external reference values are worst-case not more than 1%. The device operates correctly if the frequency remains within  $\pm$  5% of the specification limit. This tolerance range allows for a slight frequency drift of the crystals over time. The designer must thoroughly understand the drift margin of the source clock.

<sup>2</sup> All internal registers retain data at 0 Hz.

<sup>3</sup> Up to the maximum frequency rating of the device (refer to Table 1).

<sup>4</sup> Loss of reference frequency is defined as the reference frequency detected internally, which transitions the PLL into self-coded mode.

<sup>5</sup> The PLL operates at self-coded mode (SCM) frequency when the reference frequency falls below f<sub>LOR</sub>. SCM frequency is measured on the CLKOUT ball with the divider set to divide-by-two of the system clock.  
NOTE: In SCM, the MFD and PREDIV have no effect and the RFD is bypassed.

<sup>6</sup> Use the EXTAL input high voltage parameter when using the FlexCAN oscillator in crystal mode (no quartz crystals or resonators). (V<sub>extal</sub> – V<sub>xtal</sub>) must be  $\geq$  400 mV for the oscillator's comparator to produce the output clock.

<sup>7</sup> Use the EXTAL input low voltage parameter when using the FlexCAN oscillator in crystal mode (no quartz crystals or resonators). (V<sub>xtal</sub> – V<sub>extal</sub>) must be  $\geq$  400 mV for the oscillator's comparator to produce the output clock.

<sup>8</sup> I<sub>xtal</sub> is the oscillator bias current out of the XTAL pin with both EXTAL and XTAL pins grounded.

<sup>9</sup> C<sub>PCB\_EXTAL</sub> and C<sub>PCB\_XTAL</sub> are the measured PCB stray capacitances on EXTAL and XTAL, respectively.

<sup>10</sup> This specification applies to the period required for the PLL to relock after changing the MFD frequency control bits in the synthesizer control register (SYNCR). From power up with crystal oscillator reference, the lock time also includes the crystal startup time.

<sup>11</sup> PLL is operating in 1:1 PLL mode.

<sup>12</sup> V<sub>DDE</sub> = 3.0–3.6 V.

<sup>13</sup> Jitter is the average deviation from the programmed frequency measured over the specified interval at maximum f<sub>sys</sub>. Measurements are made with the device powered by filtered supplies and clocked by a stable external clock signal. Noise injected into the PLL circuitry via V<sub>DDSYN</sub> and V<sub>SSSYN</sub> and variation in crystal oscillator frequency increase the jitter percentage for a given interval. CLKOUT divider is set to divide-by-two.

<sup>14</sup> Values are with frequency modulation disabled. If frequency modulation is enabled, jitter is the sum of (jitter + Cmod).

<sup>15</sup> Modulation depth selected must not result in f<sub>sys</sub> value greater than the f<sub>sys</sub> maximum specified value.

<sup>16</sup> f<sub>sys</sub> = f<sub>ico</sub> ÷ (2<sup>RFD</sup>).

<sup>17</sup> Maximum value for dual controller (1:1) mode is (f<sub>MAX</sub> ÷ 2) with the predivider set to 1 (FMPLL\_SYNCR[PREDIV] = 0b001).

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### 3.10 eQADC Electrical Characteristics

Table 13. eQADC Conversion Specifications ( $T_A = T_L$  to  $T_H$ )

Spec	Characteristic	Symbol	Minimum	Maximum	Unit
1	ADC clock (ADCLK) frequency <sup>1</sup>	$F_{ADCLK}$	1	12	MHz
2	Conversion cycles Differential Single ended	CC	13 + 2 (15) 14 + 2 (16)	13 + 128 (141) 14 + 128 (142)	ADCLK cycles
3	Stop mode recovery time <sup>2</sup>	$T_{SR}$	10	—	$\mu s$
4	Resolution <sup>3</sup>	—	1.25	—	mV
5	INL: 6 MHz ADC clock	INL6	-4	4	Counts <sup>3</sup>
6	INL: 12 MHz ADC clock	INL12	-8	8	Counts
7	DNL: 6 MHz ADC clock	DNL6	-3 <sup>4</sup>	3 <sup>4</sup>	Counts
8	DNL: 12 MHz ADC clock	DNL12	-6 <sup>4</sup>	6 <sup>4</sup>	Counts
9	Offset error with calibration	OFFWC	-4 <sup>5</sup>	4 <sup>5</sup>	Counts
10	Full-scale gain error with calibration	GAINWC	-8 <sup>6</sup>	8 <sup>6</sup>	Counts
11	Disruptive input injection current <sup>7, 8, 9, 10</sup>	$I_{INJ}$	-1	1	mA
12	Incremental error due to injection current. All channels are $10 \text{ k}\Omega < R_s < 100 \text{ k}\Omega$ Channel under test has $R_s = 10 \text{ k}\Omega$ , $I_{INJ} = I_{INJMAX} - I_{INJMIN}$	$E_{INJ}$	-4	4	Counts
13	Total unadjusted error (TUE) for single ended conversions with calibration <sup>11, 12, 13, 14, 15</sup>	TUE	-4	4	Counts

<sup>1</sup> Conversion characteristics vary with  $F_{ADCLK}$  rate. Reduced conversion accuracy occurs at maximum  $F_{ADCLK}$  rate. The maximum value is based on 800 KS/s and the minimum value is based on 20 MHz oscillator clock frequency divided by a maximum 16 factor.

<sup>2</sup> Stop mode recovery time begins when the ADC control register enable bits are set until the ADC is ready to perform conversions.

<sup>3</sup> At  $V_{RH} - V_{RL} = 5.12 \text{ V}$ , one least significant bit (LSB) = 1.25, mV = one count.

<sup>4</sup> Guaranteed 10-bit mono tonicity.

<sup>5</sup> The absolute value of the offset error without calibration  $\leq 100$  counts.

<sup>6</sup> The absolute value of the full scale gain error without calibration  $\leq 120$  counts.

<sup>7</sup> Below disruptive current conditions, the channel being stressed has conversion values of: 0x3FF for analog inputs greater than  $V_{RH}$ , and 0x000 for values less than  $V_{RL}$ . This assumes that  $V_{RH} \leq V_{DDA}$  and  $V_{RL} \geq V_{SSA}$  due to the presence of the sample amplifier. Other channels are not affected by non-disruptive conditions.

<sup>8</sup> Exceeding the limit can cause a conversion error on both stressed and unstressed channels. Transitions within the limit do not affect device reliability or cause permanent damage.

<sup>9</sup> Input must be current limited to the value specified. To determine the value of the required current-limiting resistor, calculate resistance values using  $V_{POSCLAMP} = V_{DDA} + 0.5 \text{ V}$  and  $V_{NEGCLAMP} = -0.3 \text{ V}$ , then use the larger of the calculated values.

<sup>10</sup> This condition applies to two adjacent pads on the internal pad.

<sup>11</sup> The TUE specification is always less than the sum of the INL, DNL, offset, and gain errors due to canceling errors.

<sup>12</sup> TUE does not apply to differential conversions.

<sup>13</sup> Measured at 6 MHz ADC clock. TUE with a 12 MHz ADC clock is:  $-16 \text{ counts} < \text{TUE} < 16 \text{ counts}$ .

<sup>14</sup> TUE includes all internal device errors such as internal reference variation (75% Ref, 25% Ref).

<sup>15</sup> Depending on the input impedance, the analog input leakage current (Table 9. DC Electrical Specifications, spec 35a) can affect the actual TUE measured on analog channels AN[12], AN[13], AN[14], AN[15].

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### 3.11 H7Fa Flash Memory Electrical Characteristics

Table 14. Flash Program and Erase Specifications ( $T_A = T_L$  to  $T_H$ )

Spec	Flash Program Characteristic	Symbol	Min.	Typical <sup>1</sup>	Initial Max. <sup>2</sup>	Max. <sup>3</sup>	Unit
3	Doubleword (64 bits) program time <sup>4</sup>	$T_{dwprogram}$	—	10	—	500	μs
4	Page program time <sup>4</sup>	$T_{pprogram}$	—	22	44 <sup>5</sup>	500	μs
7	16 KB block pre-program and erase time	$T_{16kpperase}$	—	265	400	5000	ms
9	48 KB block pre-program and erase time	$T_{48kpperase}$	—	345	400	5000	ms
10	64 KB block pre-program and erase time	$T_{64kpperase}$	—	415	500	5000	ms
8	128 KB block pre-program and erase time	$T_{128kpperase}$	—	500	1250	7500	ms
11	Minimum operating frequency for program and erase operations <sup>6</sup>	—	25	—	—	—	MHz

<sup>1</sup> Typical program and erase times are calculated at 25 °C operating temperature using nominal supply values.

<sup>2</sup> Initial factory condition:  $\leq 100$  program/erase cycles, 25 °C, using a typical supply voltage measured at a minimum system frequency of 80 MHz.

<sup>3</sup> The maximum erase time occurs after the specified number of program/erase cycles. This maximum value is characterized but not guaranteed.

<sup>4</sup> Actual hardware programming times. This does not include software overhead.

<sup>5</sup> Page size is 256 bits (8 words).

<sup>6</sup> The read frequency of the flash can range up to the maximum operating frequency. There is no minimum read frequency condition.

Table 15. Flash EEPROM Module Life ( $T_A = T_L$  to  $T_H$ )

Spec	Characteristic	Symbol	Min.	Typical <sup>1</sup>	Unit
1a	Number of program/erase cycles per block for 16 KB, 48 KB, and 64 KB blocks over the operating temperature range ( $T_J$ )	P/E	100,000	—	cycles
1b	Number of program/erase cycles per block for 128 KB blocks over the operating temperature range ( $T_J$ )	P/E	1000	100,000	cycles
2	Data retention Blocks with 0–1,000 P/E cycles Blocks with 1,001–100,000 P/E cycles	Retention	20 5	— —	years

<sup>1</sup> Typical endurance is evaluated at 25° C. Product qualification is performed to the minimum specification. For additional information on the Freescale definition of typical endurance, refer to engineering bulletin EB619 Typical Endurance for Nonvolatile Memory.

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Table 16 shows the FLASH\_BIU settings versus frequency of operation. Refer to the device reference manual for definitions of these bit fields.

Table 16. FLASH\_BIU Settings vs. Frequency of Operation <sup>1</sup>

Maximum Frequency (MHz)	APC	RWSC	WWSC	DPFEN <sup>2</sup>	IPFEN <sup>2</sup>	PFLIM <sup>3</sup>	BFEN <sup>4</sup>
Up to and including 82 MHz <sup>5</sup>	0b001	0b001	0b01	0b00 0b01 0b11	0b00 0b01 0b11	0b000 to 0b110	0b0 0b1
Up to and including 102 MHz <sup>6</sup>	0b001	0b010	0b01	0b00 0b01 0b11	0b00 0b01 0b11	0b000 to 0b110	0b0 0b1
Up to and including 132 MHz <sup>7</sup>	0b010	0b011	0b01	0b00 0b01 0b11	0b00 0b01 0b11	0b000 to 0b110	0b0 0b1
Default setting after reset	0b111	0b111	0b11	0b00	0b00	0b000	0b0

<sup>1</sup> Illegal combinations exist. Use entries from the same row in this table.

<sup>2</sup> For maximum flash performance, set to 0b11.

<sup>3</sup> For maximum flash performance, set to 0b110.

<sup>4</sup> For maximum flash performance, set to 0b1.

<sup>5</sup> 82 MHz parts allow for 80 MHz system clock + 2% frequency modulation (FM).

<sup>6</sup> 102 MHz parts allow for 100 MHz system clock + 2% FM.

<sup>7</sup> 132 MHz parts allow for 128 MHz system clock + 2% FM.

## 3.12 AC Specifications

### 3.12.1 Pad AC Specifications

Table 17. Pad AC Specifications ( $V_{DDEH} = 5.0$  V,  $V_{DDE} = 1.8$  V) <sup>1</sup>

Spec	Pad	SRC / DSC (binary)	Out Delay <sup>2, 3, 4</sup> (ns)	Rise / Fall <sup>4, 5</sup> (ns)	Load Drive (pF)
1	Slow high voltage (SH)	11	26	15	50
			82	60	200
		01	75	40	50
			137	80	200
		00	377	200	50
			476	260	200
2	Medium high voltage (MH)	11	16	8	50
			43	30	200
		01	34	15	50
			61	35	200
		00	192	100	50
			239	125	200

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Table 17. Pad AC Specifications ( $V_{DDEH} = 5.0$  V,  $V_{DDE} = 1.8$  V)<sup>1</sup> (continued)

Spec	Pad	Src / DSC (binary)	Out Delay <sup>2, 3, 4</sup> (ns)	Rise / Fall <sup>4, 5</sup> (ns)	Load Drive (pF)
3	Fast	00	3.1	2.7	10
		01		2.5	20
		10		2.4	30
		11		2.3	50
4	Pullup/down (3.6 V max)	—	—	7500	50
5	Pullup/down (5.5 V max)	—	—	9000	50

<sup>1</sup> These are worst-case values that are estimated from simulation (not tested). The values in the table are simulated at:  $V_{DD} = 1.35\text{--}1.65$  V;  $V_{DDE} = 1.62\text{--}1.98$  V;  $V_{DDEH} = 4.5\text{--}5.25$  V;  $V_{DD33}$  and  $V_{DDSYN} = 3.0\text{--}3.6$  V; and  $T_A = T_L$  to  $T_H$ .

<sup>2</sup> This parameter is supplied for reference and is guaranteed by design (not tested).

<sup>3</sup> The output delay is shown in Figure 4. To calculate the output delay with respect to the system clock, add a maximum of one system clock to the output delay.

<sup>4</sup> The output delay and rise and fall are measured to 20% or 80% of the respective signal.

<sup>5</sup> This parameter is guaranteed by characterization rather than 100% tested.

Table 18. Derated Pad AC Specifications ( $V_{DDEH} = 3.3$  V,  $V_{DDE} = 3.3$  V)<sup>1</sup>

Spec	Pad	Src/DSC (binary)	Out Delay <sup>2, 3, 4</sup> (ns)	Rise / Fall <sup>3, 5</sup> (ns)	Load Drive (pF)
1	Slow high voltage (SH)	11	39	23	50
			120	87	200
		01	101	52	50
			188	111	200
		00	507	248	50
			597	312	200
		11	23	12	50
			64	44	200
2	Medium high voltage (MH)	01	50	22	50
			90	50	200
		00	261	123	50
			305	156	200
		00	3.2	2.4	10
3	Fast	01		2.2	20
		10		2.1	30
		11		2.1	50
	Pullup/down (3.6 V max)	—	—	7500	50
4	Pullup/down (5.5 V max)	—	—	9500	50

<sup>1</sup> These are worst-case values that are estimated from simulation (not tested). The values in the table are simulated at:  $V_{DD} = 1.35\text{--}1.65$  V;  $V_{DDE} = 3.0\text{--}3.6$  V;  $V_{DDEH} = 3.0\text{--}3.6$  V;  $V_{DD33}$  and  $V_{DDSYN} = 3.0\text{--}3.6$  V; and  $T_A = T_L$  to  $T_H$ .

<sup>2</sup> This parameter is supplied for reference and guaranteed by design (not tested).

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<sup>3</sup> The output delay and the rise and fall, are calculated to 20% or 80% of the respective signal.

<sup>4</sup> The output delay is shown in Figure 4. To calculate the output delay with respect to the system clock, add a maximum of one system clock to the output delay.

<sup>5</sup> This parameter is guaranteed by characterization rather than 100% tested.

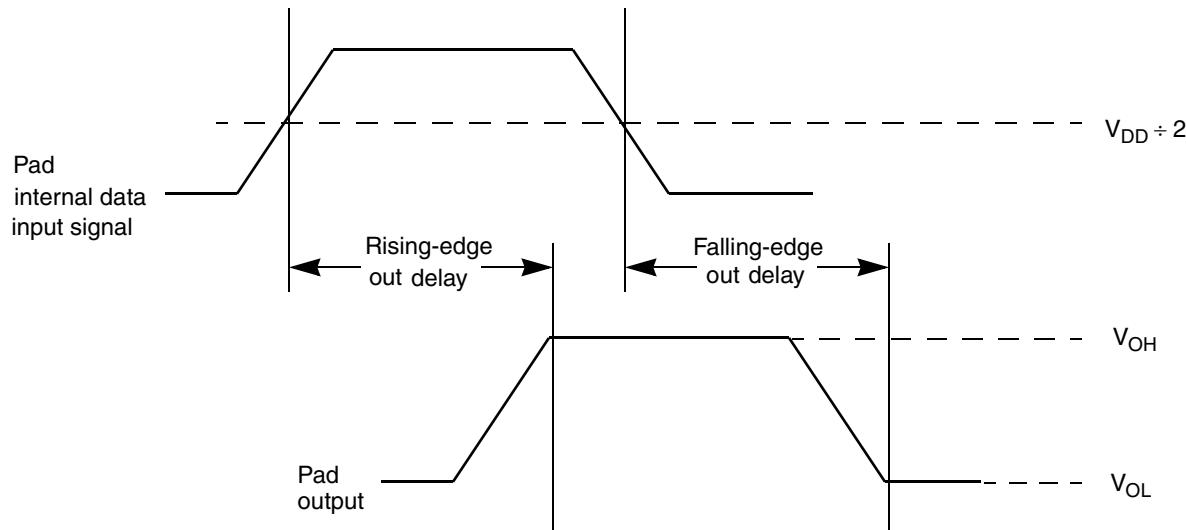


Figure 4. Pad Output Delay

## 3.13 AC Timing

### 3.13.1 Reset and Configuration Pin Timing

Table 19. Reset and Configuration Pin Timing <sup>1</sup>

Spec	Characteristic	Symbol	Min.	Max.	Unit
1	RESET pulse width	$t_{RPW}$	10	—	$t_{CYC}$
2	RESET glitch detect pulse width	$t_{GPW}$	2	—	$t_{CYC}$
3	PLLCFG, BOOTCFG, WKPCFG, RSTCFG setup time to RSTOUT valid	$t_{RCSU}$	10	—	$t_{CYC}$
4	PLLCFG, BOOTCFG, WKPCFG, RSTCFG hold time from RSTOUT valid	$t_{RCH}$	0	—	$t_{CYC}$

<sup>1</sup> Reset timing specified at:  $V_{DDEH} = 3.0\text{--}5.25\text{ V}$  and  $T_A = T_L$  to  $T_H$ .

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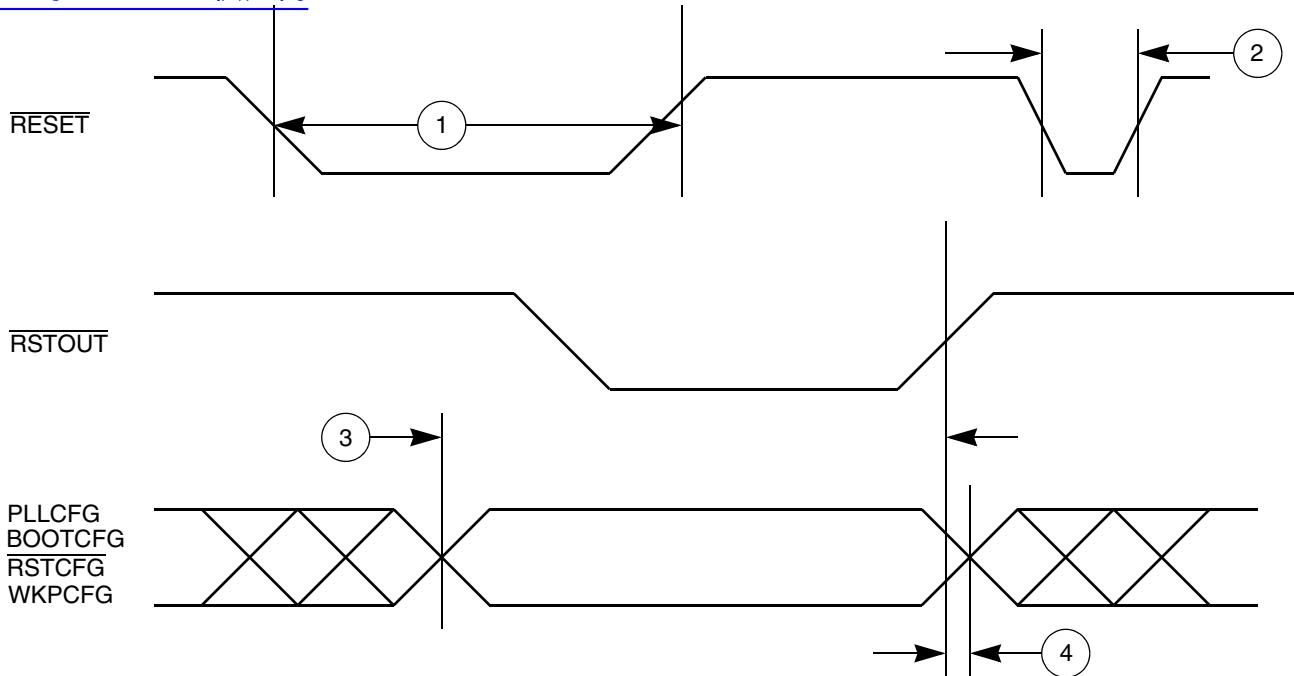


Figure 5. Reset and Configuration Pin Timing

### 3.13.2 IEEE 1149.1 Interface Timing

Table 20. JTAG Pin AC Electrical Characteristics <sup>1</sup>

Spec	Characteristic	Symbol	Min.	Max.	Unit
1	TCK cycle time	$t_{JCYC}$	100	—	ns
2	TCK clock pulse width (measured at $V_{DDE} \div 2$ )	$t_{JDC}$	40	60	ns
3	TCK rise and fall times (40% to 70%)	$t_{TCKRISE}$	—	3	ns
4	TMS, TDI data setup time	$t_{TMSS}, t_{TDIS}$	5	—	ns
5	TMS, TDI data hold time	$t_{TMSH}, t_{TDIH}$	25	—	ns
6	TCK low to TDO data valid	$t_{TDOV}$	—	20	ns
7	TCK low to TDO data invalid	$t_{TDOI}$	0	—	ns
8	TCK low to TDO high impedance	$t_{TDOHZ}$	—	20	ns
9	JCOMP assertion time	$t_{JCMPPW}$	100	—	ns
10	JCOMP setup time to TCK low	$t_{JCMPS}$	40	—	ns
11	TCK falling-edge to output valid	$t_{BSDV}$	—	50	ns
12	TCK falling-edge to output valid out of high impedance	$t_{BSDVZ}$	—	50	ns
13	TCK falling-edge to output high impedance (Hi-Z)	$t_{BSDHZ}$	—	50	ns
14	Boundary scan input valid to TCK rising-edge	$t_{BSDST}$	50	—	ns
15	TCK rising-edge to boundary scan input invalid	$t_{BSDHT}$	50	—	ns

<sup>1</sup> These specifications apply to JTAG boundary scan only. JTAG timing specified at:  $V_{DDE} = 3.0\text{--}3.6\text{ V}$  and  $T_A = T_L$  to  $T_H$ . Refer to Table 21 for Nexus specifications.

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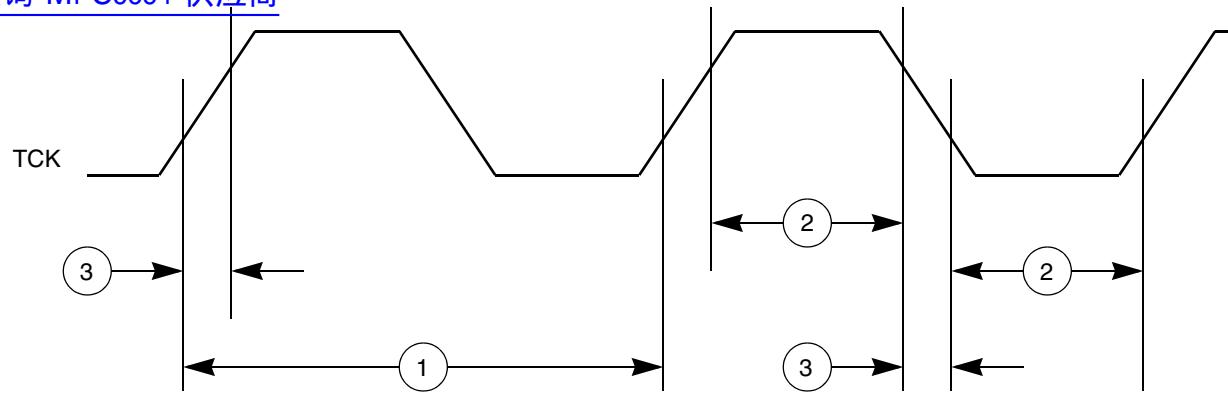


Figure 6. JTAG Test Clock Input Timing

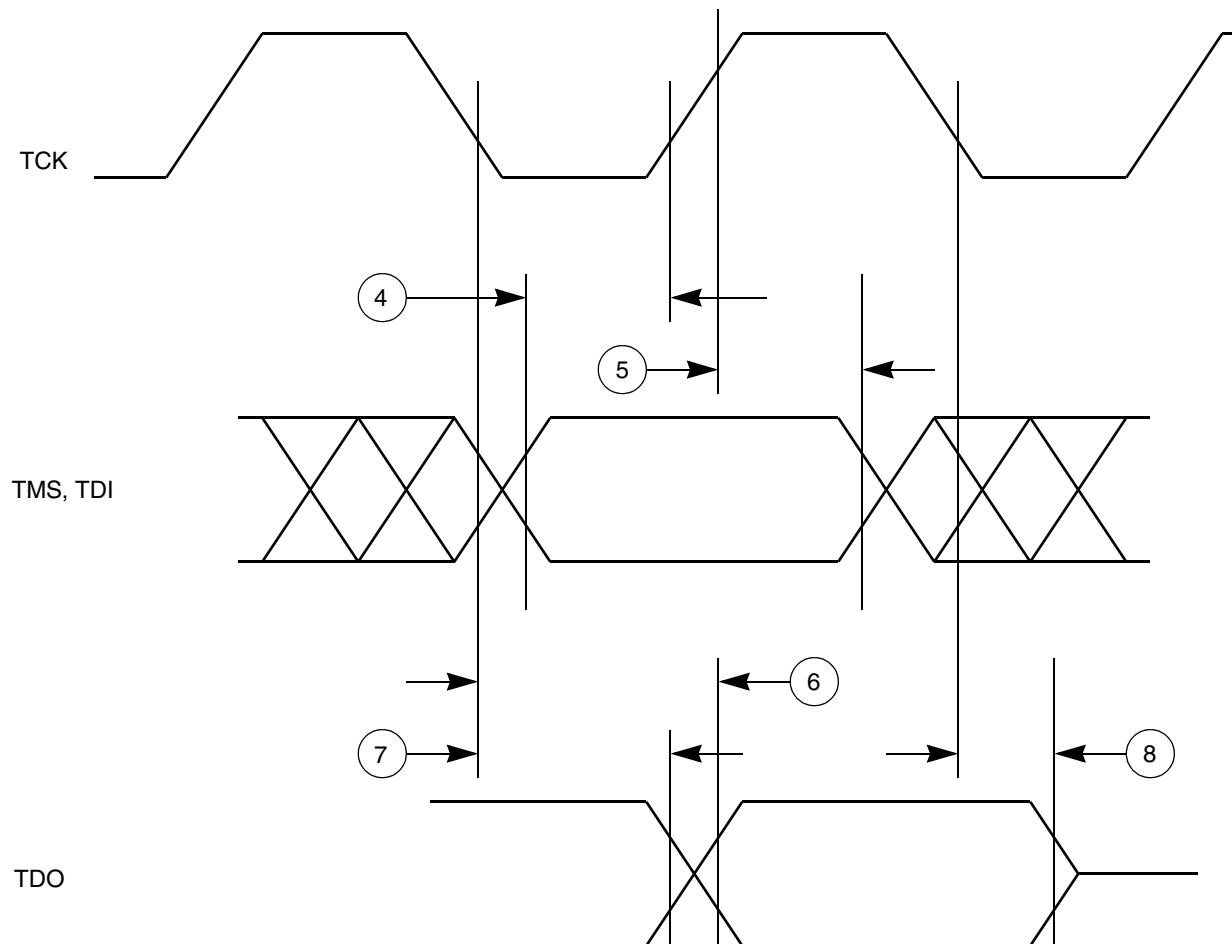


Figure 7. JTAG Test Access Port Timing

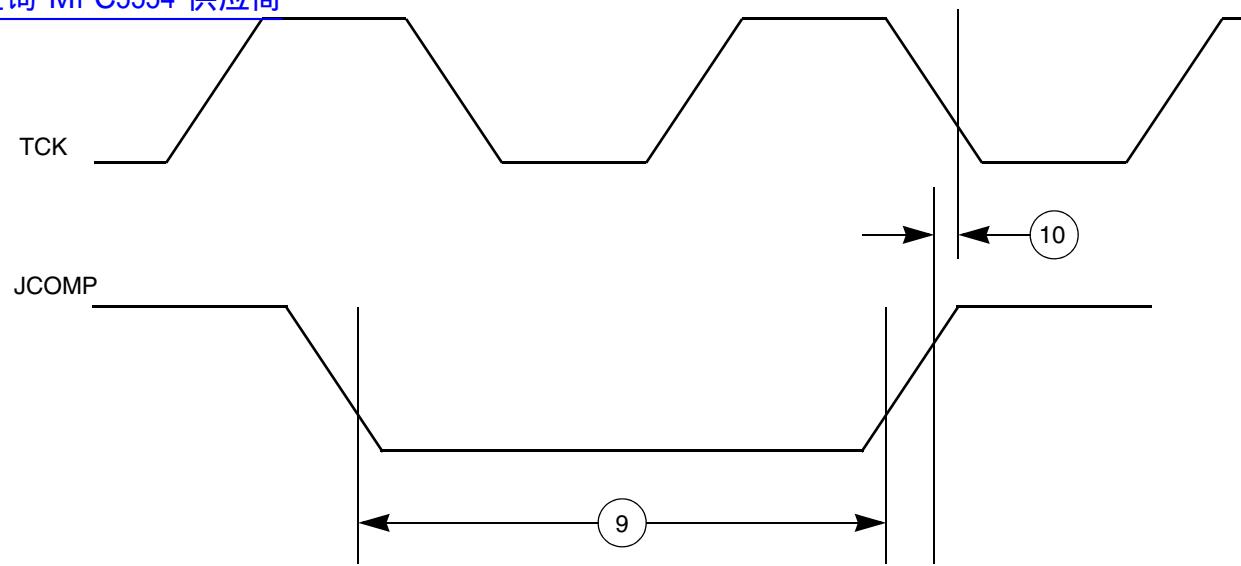
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Figure 8. JTAG JCOMP Timing

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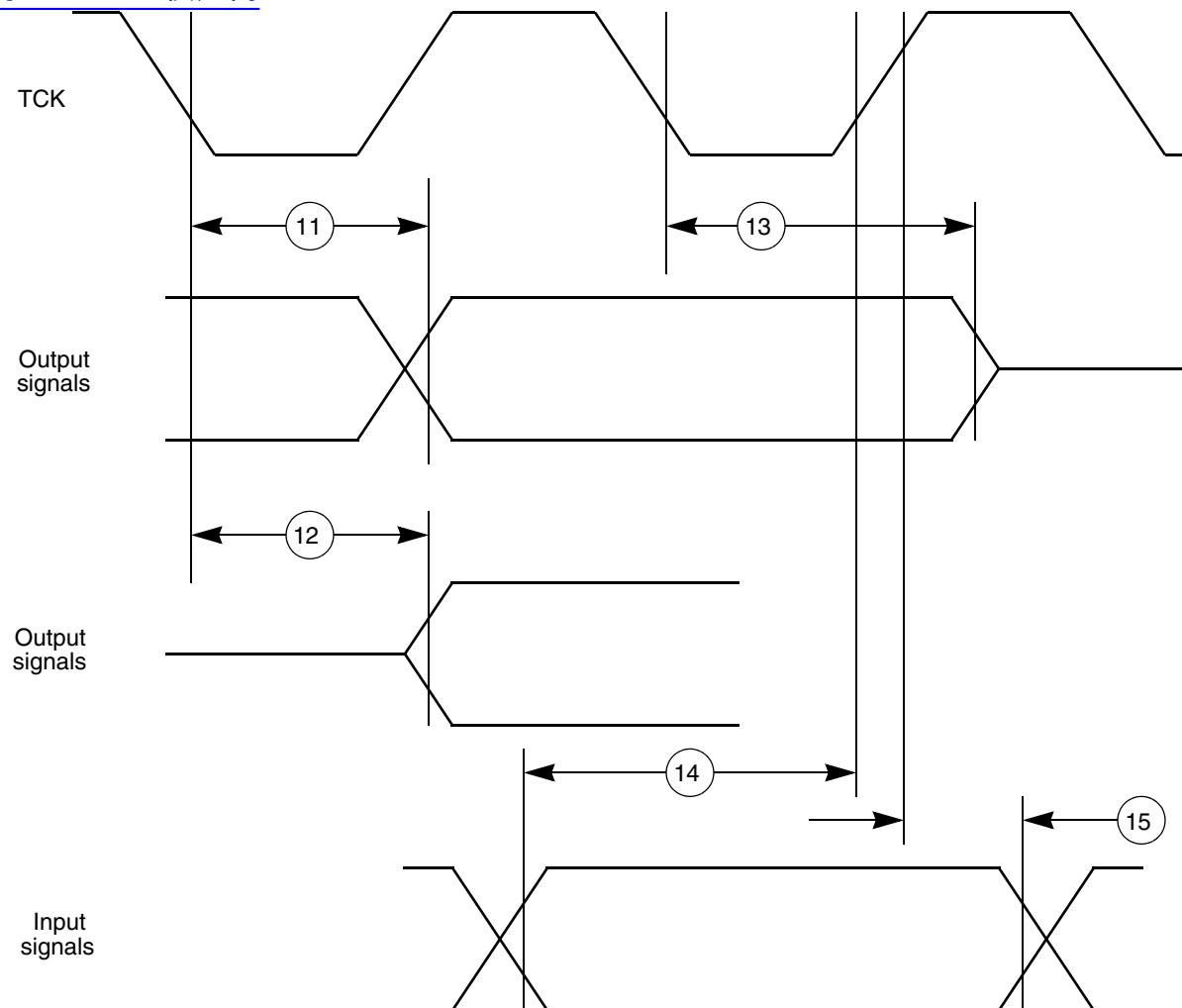


Figure 9. JTAG Boundary Scan Timing

### 3.13.3 Nexus Timing

Table 21. Nexus Debug Port Timing <sup>1</sup>

Spec	Characteristic	Symbol	Min.	Max.	Unit
1	MCKO cycle time	$t_{MCYC}$	2 <sup>2</sup>	8	$t_{CYC}$
2	MCKO duty cycle	$t_{MDC}$	40	60	%
3	MCKO low to MDO data valid <sup>3</sup>	$t_{MDOV}$	-1.5	3.0	ns
4	MCKO low to $\overline{MSEO}$ data valid <sup>3</sup>	$t_{MSEOV}$	-1.5	3.0	ns
5	MCKO low to $\overline{EVTO}$ data valid <sup>3</sup>	$t_{EVTOV}$	-1.5	3.0	ns
6	$\overline{EVTI}$ pulse width	$t_{EVТИPW}$	4.0	—	$t_{CYC}$
7	$\overline{EVTO}$ pulse width	$t_{EVTOPW}$	1	—	$t_{MCYC}$
8	TCK cycle time	$t_{TCYC}$	4 <sup>4</sup>	—	$t_{CYC}$
9	TCK duty cycle	$t_{TDC}$	40	60	%
10	TDI, TMS data setup time	$t_{NTDIS}, t_{NTMSS}$	8	—	ns
11	TDI, TMS data hold time	$t_{NTDIH}, t_{NTMSH}$	5	—	ns
12	TCK low to TDO data valid	$t_{JOV}$	0	12	ns
	$V_{DDE} = 2.25\text{--}3.0\text{ V}$		0	10	ns
	$V_{DDE} = 3.0\text{--}3.6\text{ V}$				
13	RDY valid to MCKO <sup>5</sup>	—	—	—	—

<sup>1</sup> JTAG specifications apply when used for debug functionality. All Nexus timing relative to MCKO is measured from 50% of MCKO and 50% of the respective signal. Nexus timing specified at  $V_{DD} = 1.35\text{--}1.65\text{ V}$ ,  $V_{DDE} = 2.25\text{--}3.6\text{ V}$ ,  $V_{DD33}$  and  $V_{DDSYN} = 3.0\text{--}3.6\text{ V}$ ,  $T_A = T_L$  to  $T_H$ , and  $CL = 30\text{ pF}$  with  $DSC = 0b10$ .

<sup>2</sup> The Nexus AUX port runs up to 82 MHz.

<sup>3</sup> MDO,  $\overline{MSEO}$ , and  $\overline{EVTO}$  data is held valid until the next MCKO low cycle occurs.

<sup>4</sup> Limit the maximum frequency to approximately 16 MHz ( $V_{DDE} = 2.25\text{--}3.0\text{ V}$ ) or 20 MHz ( $V_{DDE} = 3.0\text{--}3.6\text{ V}$ ) to meet the timing specification for  $t_{JOV}$  of  $[0.2 \times t_{CYC}]$  as outlined in the IEEE-ISTO 5001-2003 specification.

<sup>5</sup> The  $\overline{RDY}$  pin timing is asynchronous to MCKO and is guaranteed by design to function correctly.

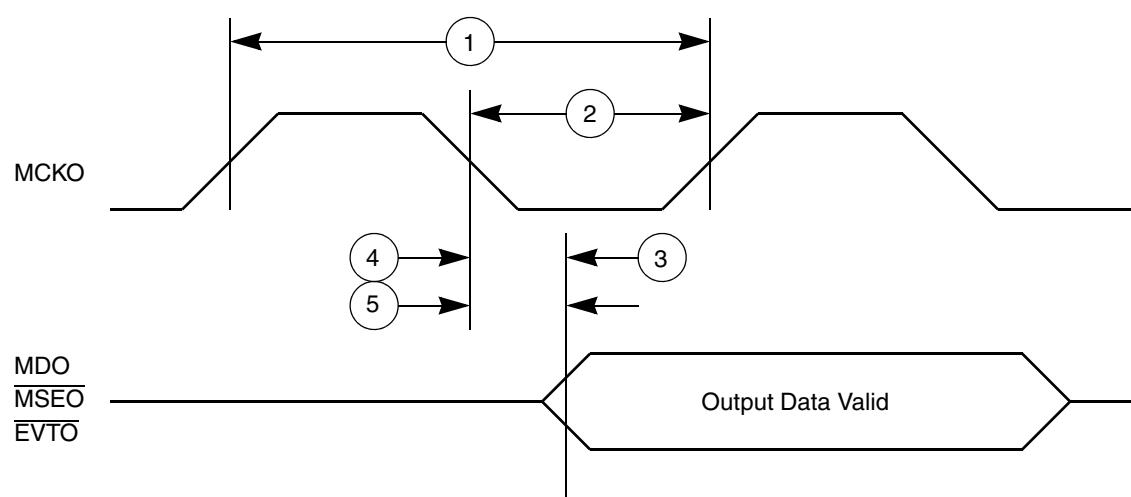


Figure 10. Nexus Output Timing

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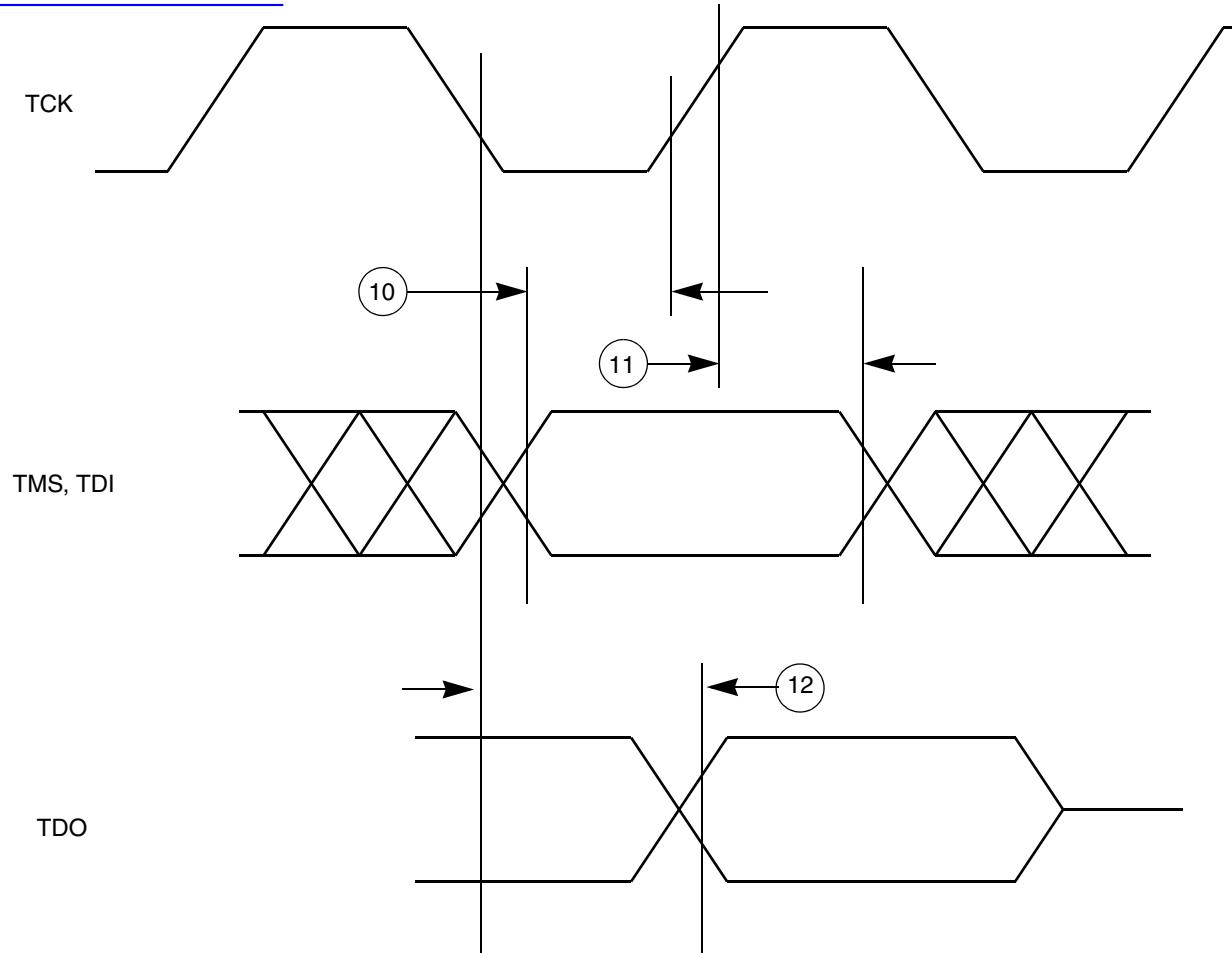


Figure 11. Nexus TDI, TMS, TDO Timing

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### 3.13.4 External Bus Interface (EBI) Timing

Table 22 lists the timing information for the external bus interface (EBI).

Table 22. Bus Operation Timing<sup>1</sup>

Spec	Characteristic and Description	Symbol	External Bus Frequency <sup>2, 3</sup>						Unit	Notes		
			40 MHz		56 MHz		66 MHz					
			Min.	Max.	Min.	Max.	Min.	Max.				
1	CLKOUT period	$T_C$	24.4	—	17.5	—	15.2	—	ns	Signals are measured at 50% $V_{DDE}$ .		
2	CLKOUT duty cycle	$t_{CDC}$	45%	55%	45%	55%	45%	55%	$T_C$			
3	CLKOUT rise time	$t_{CRT}$	—	<sup>4</sup>	—	<sup>4</sup>	—	<sup>4</sup>	ns			
4	CLKOUT fall time	$t_{CFT}$	—	<sup>4</sup>	—	<sup>4</sup>	—	<sup>4</sup>	ns			
5	CLKOUT positive edge to output signal <i>invalid</i> or Hi-Z (hold time) External bus interface $\overline{BG}$ <sup>5</sup> $\overline{BR}$ <sup>6</sup> $\overline{BB}$ $\overline{CS[0:3]}$ ADDR[8:31] DATA[0:31] $\overline{BDIP}$ $\overline{OE}$ $\overline{RD\_WR}$ $\overline{TA}$ $\overline{TEA}$ $\overline{TS}$ TSIZ[0:1] WE/BE[0:3]	$t_{COH}$	1.0 <sup>7</sup> 1.5	—	1.0 <sup>7</sup> 1.5	—	1.0 <sup>7</sup> 1.5	—	ns	EBTS = 0 EBTS = 1 Hold time selectable via SIU_ECCR [EBTS] bit.		
6	CLKOUT positive edge to output signal <i>valid</i> (output delay) External bus interface $\overline{BG}$ <sup>5</sup> $\overline{BR}$ <sup>6</sup> $\overline{BB}$ $\overline{CS[0:3]}$ ADDR[8:31] DATA[0:31] $\overline{BDIP}$ $\overline{OE}$ $\overline{RD\_WR}$ $\overline{TA}$ $\overline{TEA}$ $\overline{TS}$ TSIZ[0:1] WE/BE[0:3]	$t_{COV}$	—	10.0 <sup>7</sup> 11.0	—	7.5 <sup>7</sup> 8.5	—	6.0 <sup>7</sup> 7.0	ns	EBTS = 0 EBTS = 1 Output valid time selectable via SIU_ECCR [EBTS] bit.		

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Table 22. Bus Operation Timing<sup>1</sup> (continued)

Spec	Characteristic and Description	Symbol	External Bus Frequency <sup>2, 3</sup>						Unit	Notes		
			40 MHz		56 MHz		66 MHz					
			Min.	Max.	Min.	Max.	Min.	Max.				
7	Input signal <i>valid</i> to CLKOUT positive edge (setup time) External bus interface ADDR[8:31] DATA[0:31] $\overline{BG}$ <sup>6</sup> $\overline{BR}$ <sup>5</sup> $\overline{BB}$ $\overline{RD\_WR}$ $\overline{TA}$ $\overline{TEA}$ $\overline{TS}$	$t_{CIS}$	10.0	—	7.0	—	5.0	—	ns			
8	CLKOUT positive edge to input signal <i>invalid</i> (hold time) External bus interface ADDR[8:31] DATA[0:31] $\overline{BG}$ <sup>6</sup> $\overline{BR}$ <sup>5</sup> $\overline{BB}$ $\overline{RD\_WR}$ $\overline{TA}$ $\overline{TEA}$ $\overline{TS}$	$t_{CIH}$	1.0	—	1.0	—	1.0	—	ns			

<sup>1</sup> EBI timing specified at:  $V_{DDE} = 1.6\text{--}3.6\text{ V}$  (unless stated otherwise);  $T_A = T_L$  to  $T_H$ ; and  $CL = 30\text{ pF}$  with DSC = 0b10.

<sup>2</sup> Speed is the nominal maximum frequency. Max. speed is the maximum speed allowed including frequency modulation (FM). 82 MHz parts allow for 80 MHz system clock + 2% FM; 114 MHz parts allow for 112 MHz system clock + 2% FM; and 132 MHz parts allow for 128 MHz system clock + 2% FM.

<sup>3</sup> The external bus is limited to half the speed of the internal bus.

<sup>4</sup> Refer to fast pad timing in [Table 17](#) and [Table 18](#) (different values for 1.8 V and 3.3 V).

<sup>5</sup> Internal arbitration.

<sup>6</sup> External arbitration.

<sup>7</sup> SIU\_ECCR[EBTS] = 0 timings are tested and valid at  $V_{DDE} = 2.25\text{--}3.6\text{ V}$  only; SIU\_ECCR[EBTS] = 1 timings are tested and valid at  $V_{DDE} = 1.6\text{--}3.6\text{ V}$ .

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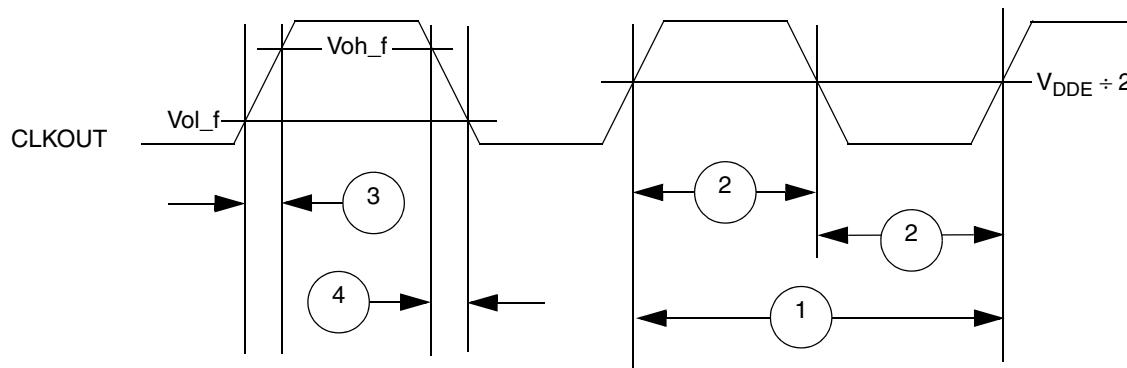


Figure 12. CLKOUT Timing

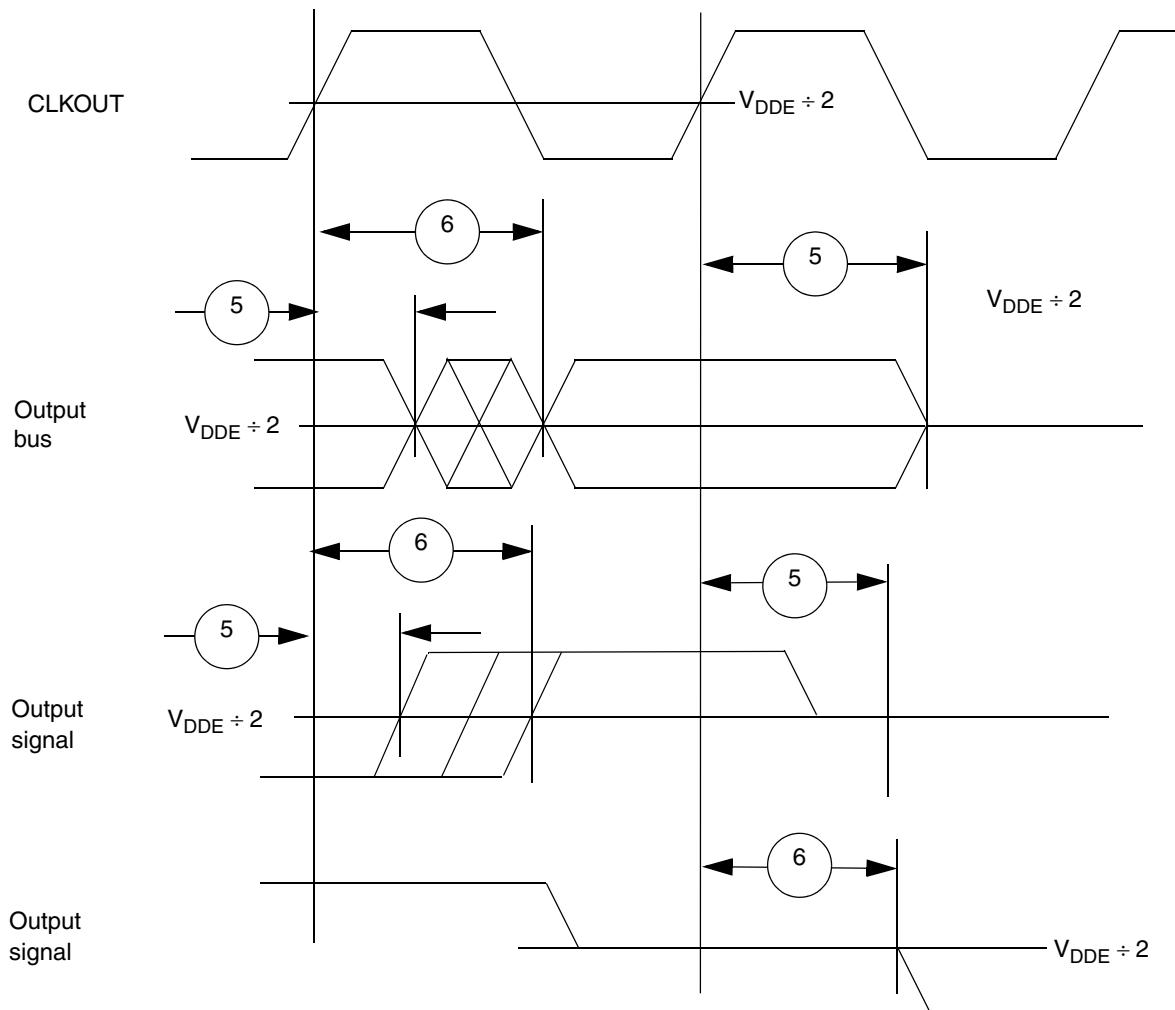


Figure 13. Synchronous Output Timing

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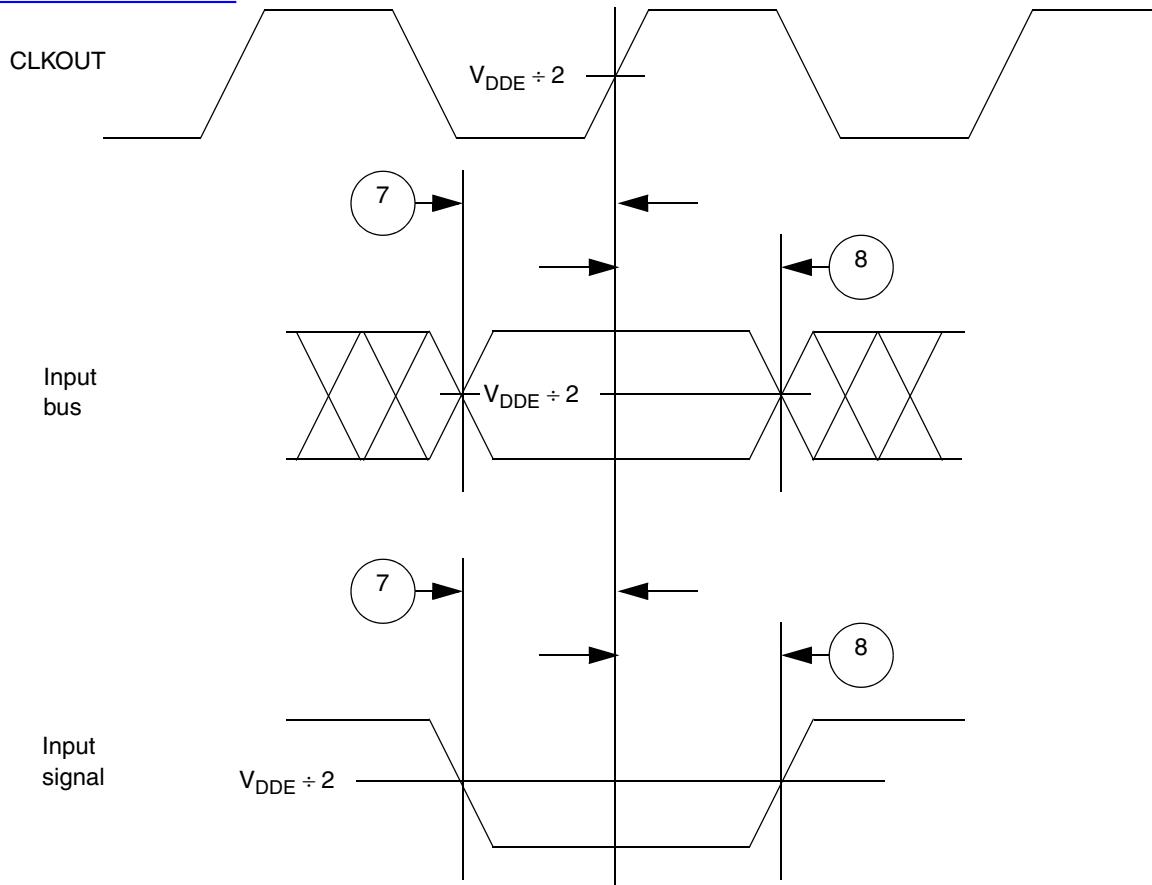


Figure 14. Synchronous Input Timing

### 3.13.5 External Interrupt Timing (IRQ Signals)

Table 23. External Interrupt Timing <sup>1</sup>

Spec	Characteristic	Symbol	Min.	Max.	Unit
1	IRQ pulse-width low	$t_{IPWL}$	3	—	$t_{CYC}$
2	IRQ pulse-width high	$T_{IPWH}$	3	—	$t_{CYC}$
3	IRQ edge-to-edge time <sup>2</sup>	$t_{ICYC}$	6	—	$t_{CYC}$

<sup>1</sup> IRQ timing specified at:  $V_{DDEH} = 3.0\text{--}5.25\text{ V}$  and  $T_A = T_L$  to  $T_H$ .

<sup>2</sup> Applies when IRQ signals are configured for rising-edge or falling-edge events, but not both.

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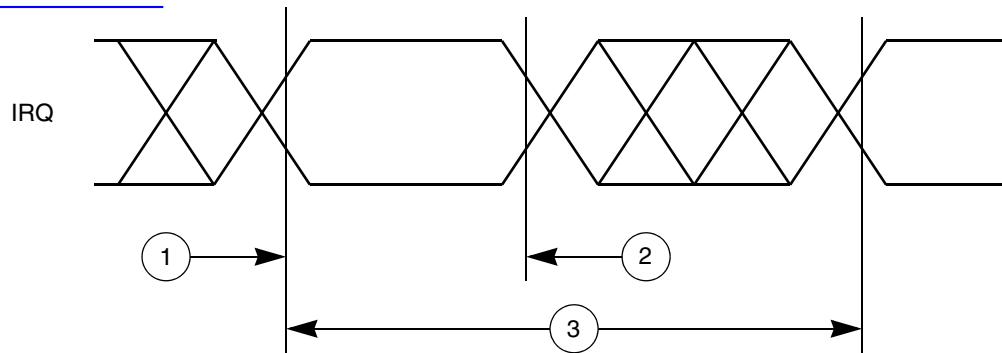


Figure 15. External Interrupt Timing

### 3.13.6 eTPU Timing

Table 24. eTPU Timing <sup>1</sup>

Spec	Characteristic	Symbol	Min.	Max	Unit
1	eTPU input channel pulse width	$t_{ICPW}$	4	—	$t_{CYC}$
2	eTPU output channel pulse width	$t_{OCPW}$	$2^2$	—	$t_{CYC}$

<sup>1</sup> eTPU timing specified at:  $V_{DDEH} = 3.0\text{--}5.25\text{ V}$  and  $T_A = T_L$  to  $T_H$ .

<sup>2</sup> This specification does not include the rise and fall times. When calculating the minimum eTPU pulse width, include the rise and fall times defined in the slew rate control fields (SRC) of the pad configuration registers (PCR).

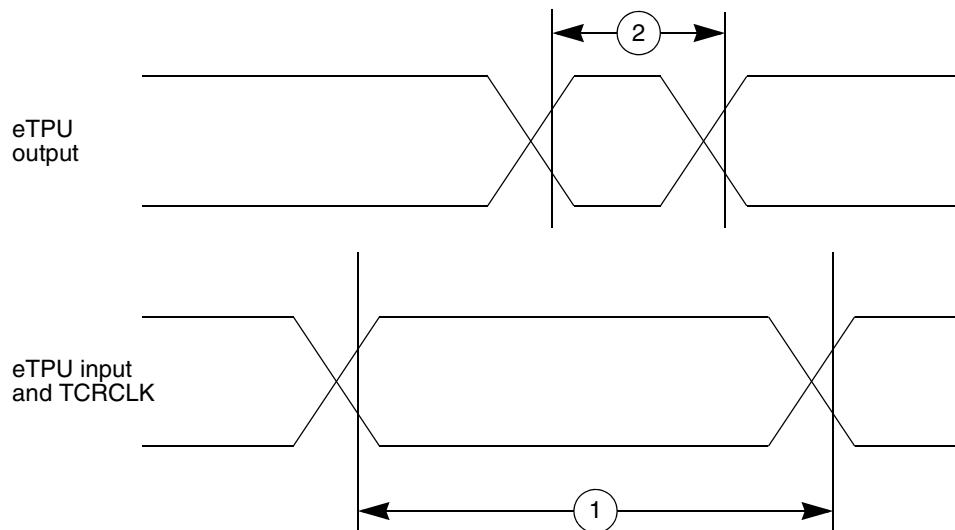


Figure 16. eTPU Timing

## Electrical Characteristics

### 3.13.7 eMOS Timing

Table 25. eMOS Timing <sup>1</sup>

Spec	Characteristic	Symbol	Min.	Max.	Unit
1	eMOS input pulse width	$t_{MIPW}$	4	—	$t_{CYC}$
2	eMOS output pulse width	$t_{MOPW}$	1 <sup>2</sup>	—	$t_{CYC}$

<sup>1</sup> eMOS timing specified at:  $V_{DDEH} = 3.0\text{--}5.25\text{ V}$  and  $T_A = T_L$  to  $T_H$ .

<sup>2</sup> This specification does not include the rise and fall times. When calculating the minimum eMOS pulse width, include the rise and fall times defined in the slew rate control field (SRC) in the pad configuration register (PCR).

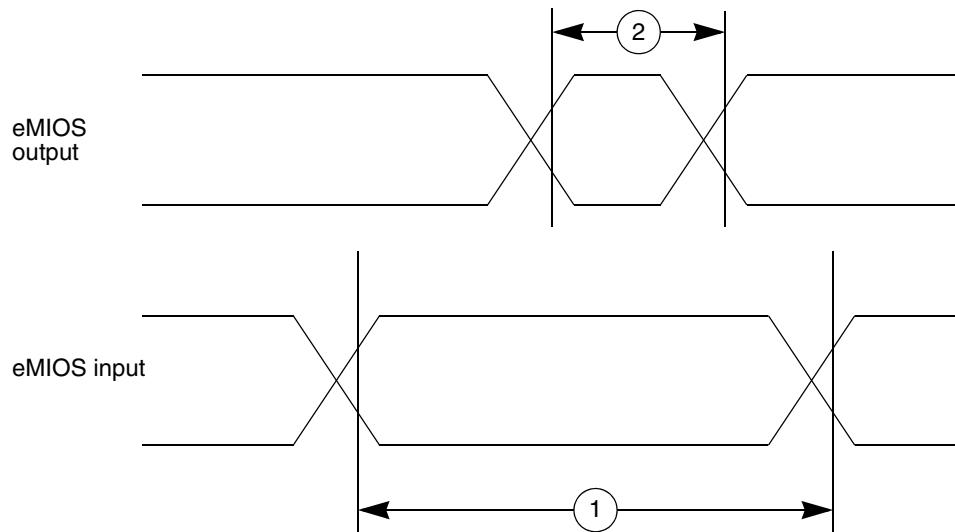


Figure 17. eMOS Timing

### 3.13.8 DSPI Timing

Table 26. DSPI Timing <sup>1, 2</sup>

Spec	Characteristic	Symbol	80 MHz		112 MHz		132 MHz		Unit
			Min.	Max.	Min.	Max.	Min.	Max.	
1	SCK cycle time <sup>3, 4</sup>	$t_{SCK}$	24.4 ns	2.9 ms	17.5 ns	2.1 ms	15.2 ns	1.7 ms	—
2	PCS to SCK delay <sup>5</sup>	$t_{CSC}$	23	—	15	—	13	—	ns
3	After SCK delay <sup>6</sup>	$t_{ASC}$	22	—	14	—	12	—	ns
4	SCK duty cycle	$t_{SDC}$	$(t_{SCK} \div 2) - 2\text{ ns}$	$(t_{SCK} \div 2) + 2\text{ ns}$	$(t_{SCK} \div 2) - 2\text{ ns}$	$(t_{SCK} \div 2) + 2\text{ ns}$	$(t_{SCK} \div 2) - 2\text{ ns}$	$(t_{SCK} \div 2) + 2\text{ ns}$	ns
5	Slave access time ( $\overline{SS}$ active to SOUT driven)	$t_A$	—	25	—	25	—	25	ns
6	Slave SOUT disable time ( $\overline{SS}$ inactive to SOUT Hi-Z, or invalid)	$t_{DIS}$	—	25	—	25	—	25	ns
7	PCSx to $\overline{PCSS}$ time	$t_{PCSC}$	4	—	4	—	4	—	ns
8	$\overline{PCSS}$ to PCSx time	$t_{PASC}$	5	—	5	—	5	—	ns

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Table 26. DSPI Timing<sup>1, 2</sup> (continued)

Spec	Characteristic	Symbol	80 MHz		112 MHz		132 MHz		Unit
			Min.	Max.	Min.	Max.	Min.	Max.	
9	Data setup time for inputs	t <sub>SUI</sub>							
	Master (MTFE = 0)		20	—	20	—	20	—	ns
	Slave		2	—	2	—	2	—	ns
	Master (MTFE = 1, CPHA = 0) <sup>7</sup>		-4	—	3	—	6	—	ns
10	Data hold time for inputs	t <sub>HI</sub>							
	Master (MTFE = 0)		-4	—	-4	—	-4	—	ns
	Slave		7	—	7	—	7	—	ns
	Master (MTFE = 1, CPHA = 0) <sup>7</sup>		21	—	14	—	12	—	ns
11	Data valid (after SCK edge)	t <sub>SUO</sub>							
	Master (MTFE = 0)		—	5	—	5	—	5	ns
	Slave		—	25	—	25	—	25	ns
	Master (MTFE = 1, CPHA = 0)		—	18	—	14	—	13	ns
12	Data hold time for outputs	t <sub>HO</sub>							
	Master (MTFE = 0)		-5	—	-5	—	-5	—	ns
	Slave		5.5	—	5.5	—	5.5	—	ns
	Master (MTFE = 1, CPHA = 0)		8	—	4	—	3	—	ns
	Master (MTFE = 1, CPHA = 1)		-5	—	-5	—	-5	—	ns

<sup>1</sup> All DSPI timing specifications use the fastest slew rate (SRC = 0b11) on pad type M or MH. DSPI signals using pad types of S or SH have an additional delay based on the slew rate. DSPI timing is specified at: V<sub>DDEH</sub> = 3.0–5.25 V; T<sub>A</sub> = T<sub>L</sub> to T<sub>H</sub>; and CL = 50 pF with SRC = 0b11.

<sup>2</sup> Speed is the nominal maximum frequency. Max. speed is the maximum speed allowed including frequency modulation (FM). 82 MHz parts allow for 80 MHz system clock + 2% FM; 114 MHz parts allow for 112 MHz system clock + 2% FM; and 132 MHz parts allow for 128 MHz system clock + 2% FM.

<sup>3</sup> The minimum SCK cycle time restricts the baud rate selection for the given system clock rate. These numbers are calculated based on two MPC55xx devices communicating over a DSPI link.

<sup>4</sup> The actual minimum SCK cycle time is limited by pad performance.

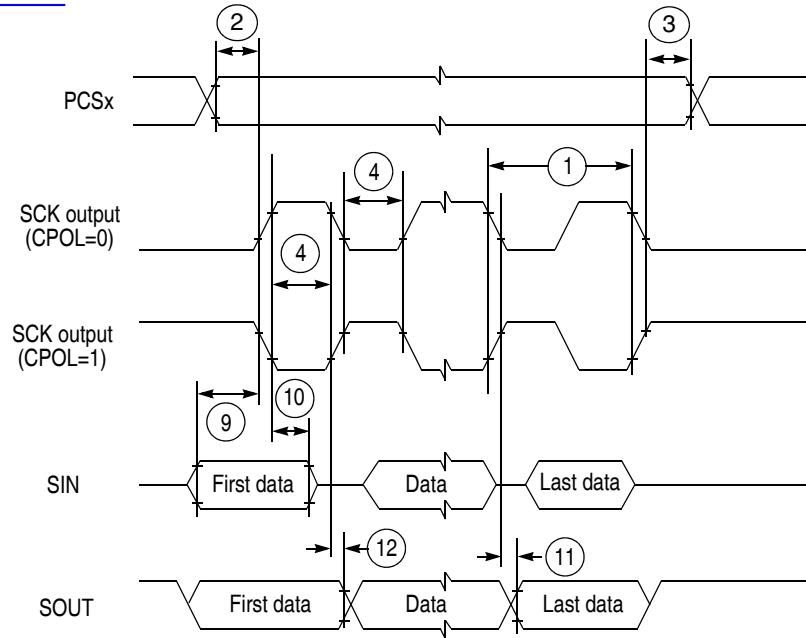
<sup>5</sup> The maximum value is programmable in DSPI\_CTARx[PSSCK] and DSPI\_CTARx[CSSCK].

<sup>6</sup> The maximum value is programmable in DSPI\_CTARx[PASC] and DSPI\_CTARx[ASC].

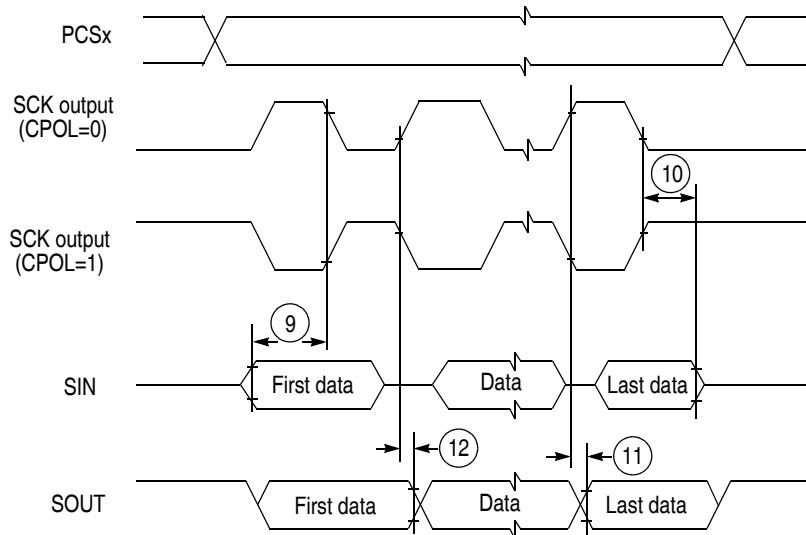
<sup>7</sup> This number is calculated using the SMPL\_PT field in DSPI\_MCR set to 0b10.

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**Figure 18. DSPI Classic SPI Timing—Master, CPHA = 0**



**Figure 19. DSPI Classic SPI Timing—Master, CPHA = 1**

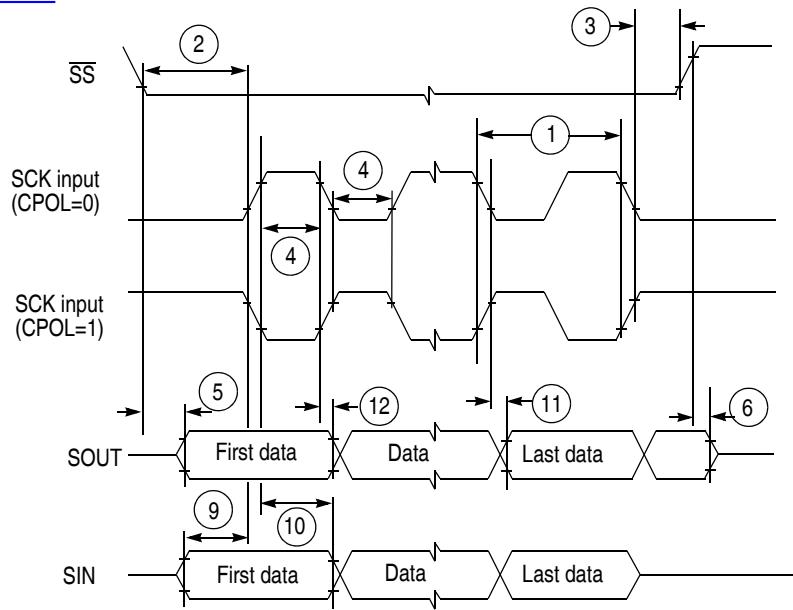
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Figure 20. DSPI Classic SPI Timing—Slave, CPHA = 0

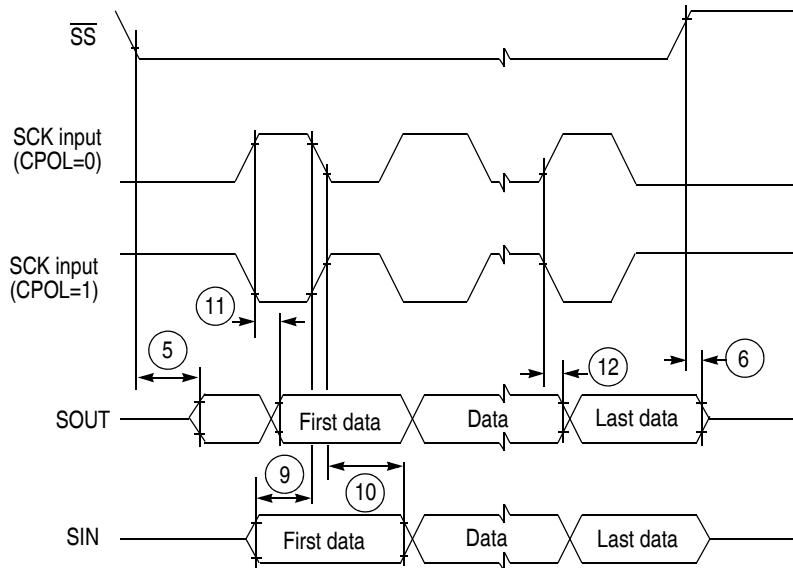


Figure 21. DSPI Classic SPI Timing—Slave, CPHA = 1

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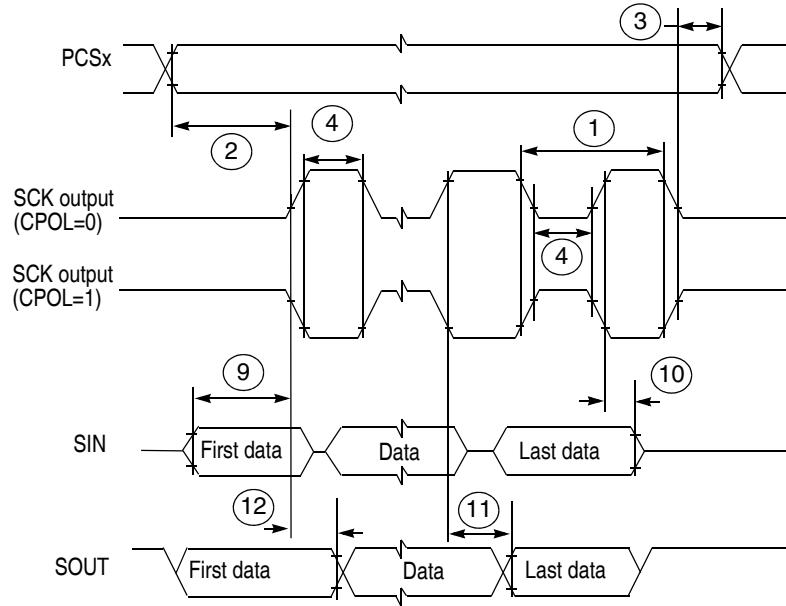


Figure 22. DSPI Modified Transfer Format Timing—Master, CPHA = 0

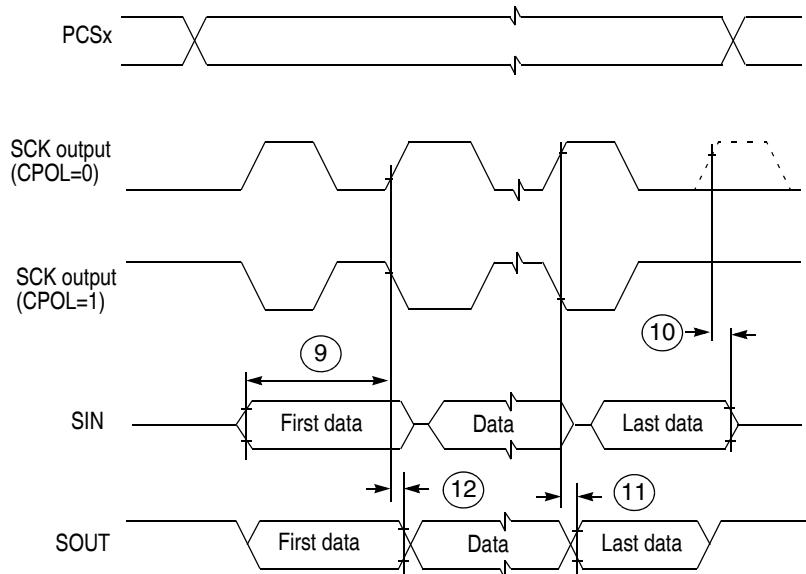


Figure 23. DSPI Modified Transfer Format Timing—Master, CPHA = 1

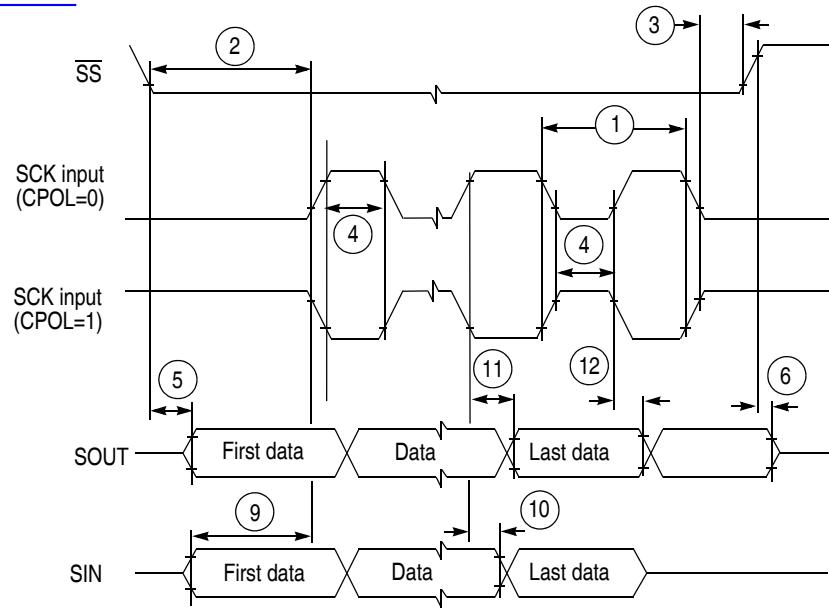
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Figure 24. DSPI Modified Transfer Format Timing—Slave, CPHA = 0

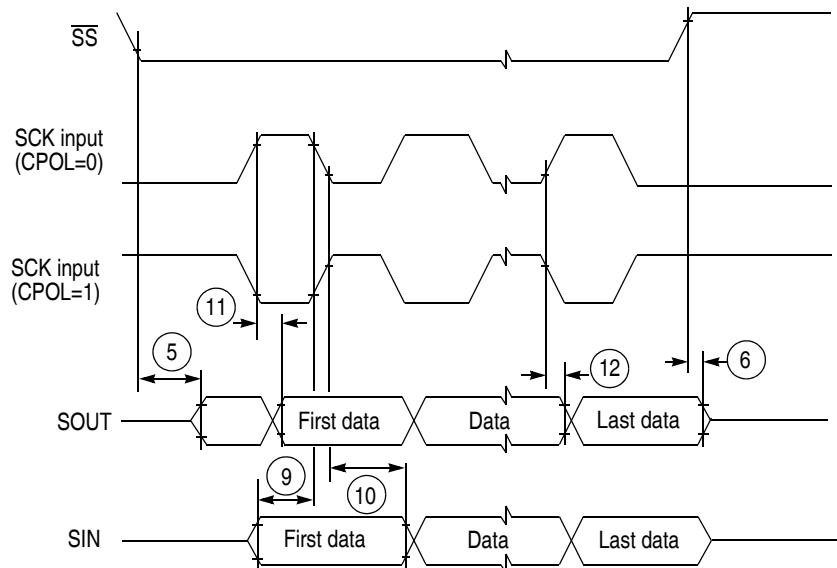


Figure 25. DSPI Modified Transfer Format Timing—Slave, CPHA = 1

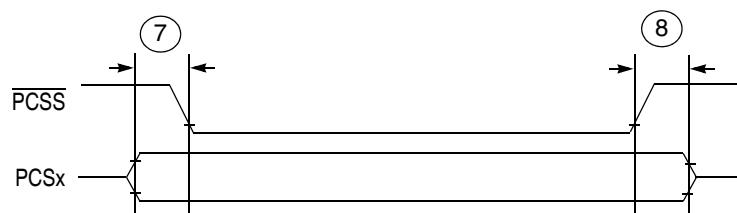


Figure 26. DSPI PCS Strobe (PCSS) Timing

## Electrical Characteristics

### 3.13.9 eQADC SSI Timing

Table 27. EQADC SSI Timing Characteristics

Spec	Rating	Symbol	Minimum	Typical	Maximum	Unit
2	FCK period ( $t_{FCK} = 1 \div f_{FCK}$ ) <sup>1, 2</sup>	$t_{FCK}$	2	—	17	$t_{SYS\_CLK}$
3	Clock (FCK) high time	$t_{FCKHT}$	$t_{SYS\_CLK} - 6.5$	—	$9 \times (t_{SYS\_CLK} + 6.5)$	ns
4	Clock (FCK) low time	$t_{FCKLT}$	$t_{SYS\_CLK} - 6.5$	—	$8 \times (t_{SYS\_CLK} + 6.5)$	ns
5	SDS lead / lag time	$t_{SDS\_LL}$	-7.5	—	+7.5	ns
6	SDO lead / lag time	$t_{SDO\_LL}$	-7.5	—	+7.5	ns
7	EQADC data setup time (inputs)	$t_{EQ\_SU}$	22	—	—	ns
8	EQADC data hold time (inputs)	$t_{EQ\_HO}$	1	—	—	ns

<sup>1</sup> SS timing specified at  $V_{DDEH} = 3.0\text{--}5.25$  V,  $T_A = T_L$  to  $T_H$ , and  $CL = 25$  pF with  $SRC = 0b11$ . Maximum operating frequency varies depending on track delays, master pad delays, and slave pad delays.

<sup>2</sup> FCK duty cycle is not 50% when it is generated through the division of the system clock by an odd number.

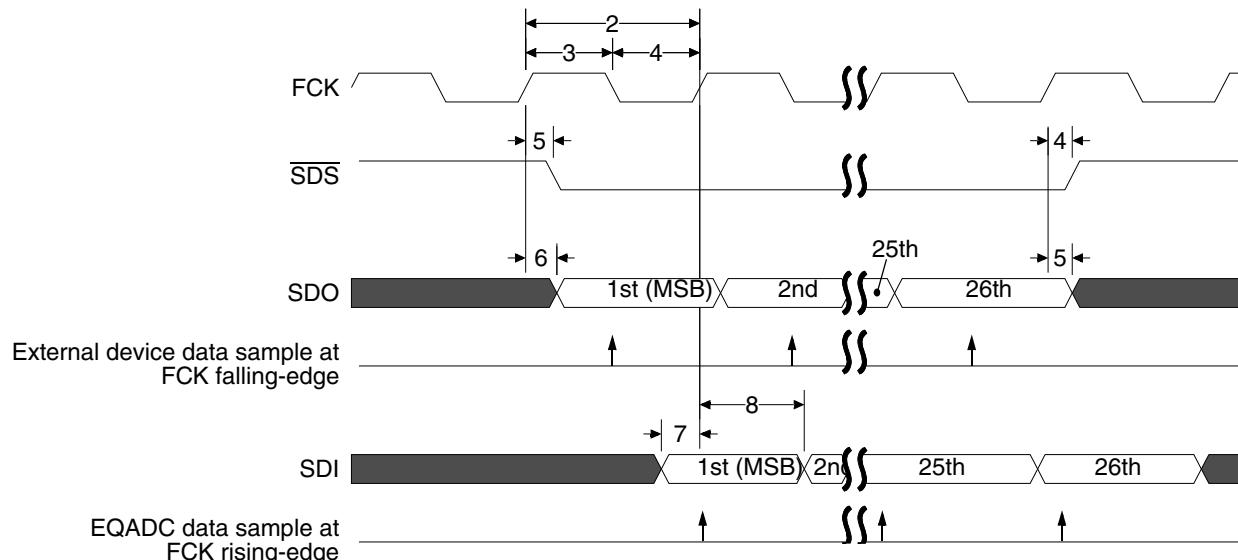


Figure 27. EQADC SSI Timing

## 4 Mechanicals

### 4.1 MPC5554 416 PBGA Pinout

Figure 28, Figure 29, and Figure 30 show the pinout for the MPC5554 416 PBGA package.

#### NOTE

The MPC5500 devices are pin compatible for software portability and use the primary function names to label the pins in the BGA diagram. Although some devices do not support all the primary functions shown in the BGA diagram, the muxed and GPIO signals on those pins remain available. See the signals chapter in the device reference manual for the signal muxing.

	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20	21	22	23	24	25	26
A	VSS	VSTBY	AN37	AN11	VDDA1	AN16	AN1	AN5	VRH	AN23	AN27	AN28	AN35	VSSA0	AN15	ETRIG1	ETPUB18	ETPUB20	ETPUB24	ETPUB27	GPIO205	MDO11	MDO8	VDD	VDD33	VSS
B	VDD	VSS	AN36	AN39	AN19	AN20	AN0	AN4	REF_BYPC	AN22	AN26	AN31	AN32	VSSA0	AN14	ETRIG0	ETPUB21	ETPUB25	ETPUB28	ETPUB31	MDO10	MDO7	MDO4	MDO0	VSS	VDDE7
C	VDD33	VDD	VSS	AN8	AN17	VSSA1	AN21	AN3	AN7	VRL	AN25	AN30	AN33	VDDAO	AN13	ETPUB19	ETPUB22	ETPUB26	ETPUB30	MDO9	MDO6	MDO3	MDO1	VSS	VDDE7	VDD
D	ETPUA30	ETPUA31	VDD	VSS	AN38	AN9	AN10	AN18	AN2	AN6	AN24	AN29	AN34	VDDEH9	AN12	ETPUB16	ETPUB17	ETPUB23	ETPUB29	MDO5	MDO2	VDDEH9	VSS	VDDE7	TCK	TDI
E	ETPUA28	ETPUA29	VDDEH1	VDD																						VDDE7
F	ETPUA24	ETPUA27	ETPUA26	VDDEH1																						MSE00
G	ETPUA23	ETPUA22	ETPUA25	ETPUA21																						MSE01
H	ETPUA20	ETPUA19	ETPUA18	ETPUA17																						RDY
J	ETPUA16	ETPUA15	ETPUA14	ETPUA13																						ETPUB15
K	ETPUA12	ETPUA11	ETPUA10	ETPUA9																						ETPUB14
L	ETPUA8	ETPUA7	ETPUA6	ETPUA5																						ETPUB13
M	ETPUA4	ETPUA3	ETPUA2	ETPUA1																						ETPUB9
N	BDIP	TEA	ETPUA0	TCRCLKA																						SOUTB
P	CS3	CS2	CS1	CS0																						PCSB3
R	WE3	WE2	WE1	WE0																						PCSB0
T	VDDE2	TSIZ0	RD_WR	VDDE2																						PCSB1
U	ADDR16	TSIZ1	TA	VDDE33																						PCSA4
V	ADDR18	ADDR17	TS	ADDR8																						CNTXC
W	ADDR20	ADDR19	ADDR9	ADDR10																						RST_CFG
Y	ADDR22	ADDR21	ADDR11	VDDE2																						RXDB
AA	ADDR24	ADDR23	ADDR13	ADDR12																						WKP_CFG
AB	VDDE2	ADDR25	ADDR15	ADDR14																						PLL_CFG1
AC	ADDR26	ADDR27	ADDR31	VSS	VDD	DATA26	DATA28	VDDE2	DATA30	DATA31	DATA8	DATA10	VDDE2	DATA12	DATA14	EMIOS2	EMIOS8	EMIOS12	EMIOS21	VDDE5	NC	VSS	VDD	VRC33	VDD_SYN	
AD	ADDR28	ADDR30	VSS	VDD	DATA24	DATA25	DATA27	DATA29	VDDE33	GPIO207	DATA9	DATA11	DATA13	DATA15	EMIOS3	EMIOS6	EMIOS10	EMIOS15	EMIOS17	EMIOS22	CNTXA	VDDE5	NC	VSS	VDD	VDD33
AE	ADDR29	VSS	VDD	DATA17	DATA19	DATA21	DATA23	DATA0	DATA2	DATA4	DATA6	OE	BR	BG	EMIOS1	EMIOS5	EMIOS9	EMIOS13	EMIOS16	EMIOS19	EMIOS23	CNRXA	VDDE5	CLKOUT	VSS	VDD
AF	VSS	VDD	DATA16	DATA18	VDDE2	DATA20	DATA22	GPIO206	DATA1	DATA3	VDDE2	DATA5	DATA7	BB	EMIOS0	EMIOS4	EMIOS7	EMIOS11	EMIOS14	EMIOS18	EMIOS20	CNTXB	CNRXB	VDDE5	ENG_CLK	VSS
	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20	21	22	23	24	25	26

Figure 28. MPC5554 416 Package

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	1	2	3	4	5	6	7	8	9	10	11	12	13
A	VSS	VSTBY	AN37	AN11	VDDA1	AN16	AN1	AN5	VRH	AN23	AN27	AN28	AN35
B	VDD	VSS	AN36	AN39	AN19	AN20	AN0	AN4	REF BYPC	AN22	AN26	AN31	AN32
C	VDD33	VDD	VSS	AN8	AN17	VSSA1	AN21	AN3	AN7	VRL	AN25	AN30	AN33
D	ETPUA 30	ETPUA 31	VDD	VSS	AN38	AN9	AN10	AN18	AN2	AN6	AN24	AN29	AN34
E	ETPUA 28	ETPUA 29	VDDEH 1	VDD									
F	ETPUA 24	ETPUA 27	ETPUA 26	VDDEH 1									
G	ETPUA 23	ETPUA 22	ETPUA 25	ETPUA 21									
H	ETPUA 20	ETPUA 19	ETPUA 18	ETPUA 17									
J	ETPUA 16	ETPUA 15	ETPUA 14	ETPUA 13									
K	ETPUA 12	ETPUA 11	ETPUA 10	ETPUA 9									
L	ETPUA 8	ETPUA 7	ETPUA 6	ETPUA 5									
M	ETPUA 4	ETPUA 3	ETPUA 2	ETPUA 1									
N	BDIP	TEA	ETPUA 0	TCRCLK A									
P	CS3	CS2	CS1	CS0									
R	WE3	WE2	WE1	WE0									
T	VDDE2	TSIZ0	RD_WR	VDDE2									
U	ADDR 16	TSIZ1	TA	VDD33									
V	ADDR 18	ADDR 17	TS	ADDR 8									
W	ADDR 20	ADDR 19	ADDR 9	ADDR 10									
Y	ADDR 22	ADDR 21	ADDR 11	VDDE2									
AA	ADDR 24	ADDR 23	ADDR 13	ADDR 12									
AB	VDDE2	ADDR 25	ADDR 15	ADDR 14									
AC	ADDR 26	ADDR 27	ADDR 31	VSS	VDD	DATA 26	DATA 28	VDDE2	DATA 30	DATA 31	DATA 8	DATA 10	VDDE2
AD	ADDR 28	ADDR 30	VSS	VDD	DATA 24	DATA 25	DATA 27	DATA 29	VDD33	GPIO 207	DATA 9	DATA 11	DATA 13
AE	ADDR 29	VSS	VDD	DATA 17	DATA 19	DATA 21	DATA 23	DATA 0	DATA 2	DATA 4	DATA 6	OE	BR
AF	VSS	VDD	DATA 16	DATA 18	VDDE2	DATA 20	DATA 22	GPIO 206	DATA 1	DATA 3	VDDE2	DATA 5	DATA 7
	1	2	3	4	5	6	7	8	9	10	11	12	13

Figure 29. MPC554 416 Package Left Side (view 1 of 2)

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14	15	16	17	18	19	20	21	22	23	24	25	26	
VSSA0	AN15	ETRIG 1	ETPUB 18	ETPUB 20	ETPUB 24	ETPUB 27	GPIO 205	MDO11	MDO8	VDD	VDD33	VSS	A
VSSA0	AN14	ETRIG 0	ETPUB 21	ETPUB 25	ETPUB 28	ETPUB 31	MDO10	MDO7	MDO4	MDO0	VSS	VDDE7	B
VDDA0	AN13	ETPUB 19	ETPUB 22	ETPUB 26	ETPUB 30	MDO9	MDO6	MDO3	MDO1	VSS	VDDE7	VDD	C
VDDEH 9	AN12	ETPUB 16	ETPUB 17	ETPUB 23	ETPUB 29	MDO5	MDO2	VDDEH 8	VSS	VDDE7	TCK	TDI	D
										VDDE7	TMS	TDO	TEST
										MSE00	JCOMP	EVTI	EVTO
										MSE01	MCKO	GPIO 204	ETPUB 15
										RDY	GPIO 203	ETPUB 14	ETPUB 13
										VDDEH 6	ETPUB 12	ETPUB 11	ETPUB 9
										ETPUB 10	ETPUB 8	ETPUB 7	ETPUB 5
										ETPUB 6	ETPUB 4	ETPUB 3	ETPUB 2
										TCRCLK B	ETPUB 1	ETPUB 0	SINB
										SOUTB	PCSB3	PCSB0	PCSB1
										PCSA3	PCSB4	SCKB	PCSB2
										PCSB5	SOUTA	SINA	SCKA
										PCSA1	PCSA0	PCSA2	VPP
										PCSA4	TXDA	PCSA5	VFLASH
										CNTXC	RXDA	RSTOUT	RST CFG
										RXDB	CNRXC	TXDB	RESET
										WKP CFG	BOOT CFG1	VRC VSS	VSS SYN
										VDDEH 6	PLL CFG1	BOOT CFG0	EXTAL
										VDD	VRC CTL	PLL CFG0	XTAL
DATA 12	DATA 14	EMIOS 2	EMIOS 8	EMIOS 12	EMIOS 21	VDDEH 4	VDDE5	NC	VSS	VDD	VRC33	VDD SYN	AC
DATA 15	EMIOS 3	EMIOS 6	EMIOS 10	EMIOS 15	EMIOS 17	EMIOS 22	CNTXA	VDDE5	NC	VSS	VDD	VDD33	AD
BG	EMIOS 1	EMIOS 5	EMIOS 9	EMIOS 13	EMIOS 16	EMIOS 19	EMIOS 23	CNRXA	VDDE5	CLKOUT	VSS	VDD	AE
BB	EMIOS 0	EMIOS 4	EMIOS 7	EMIOS 11	EMIOS 14	EMIOS 18	EMIOS 20	CNTXB	CNRXB	VDDE5	ENG CLK	VSS	AF
14	15	16	17	18	19	20	21	22	23	24	25	26	

Figure 30. MPC5554 416 Package Right Side (view 2 of 2)

## Mechanicals

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## 4.2 MPC5554 416-Pin Package Dimensions

The package drawings of the MPC5554 416 pin TEPBGA package are shown in Figure 31.

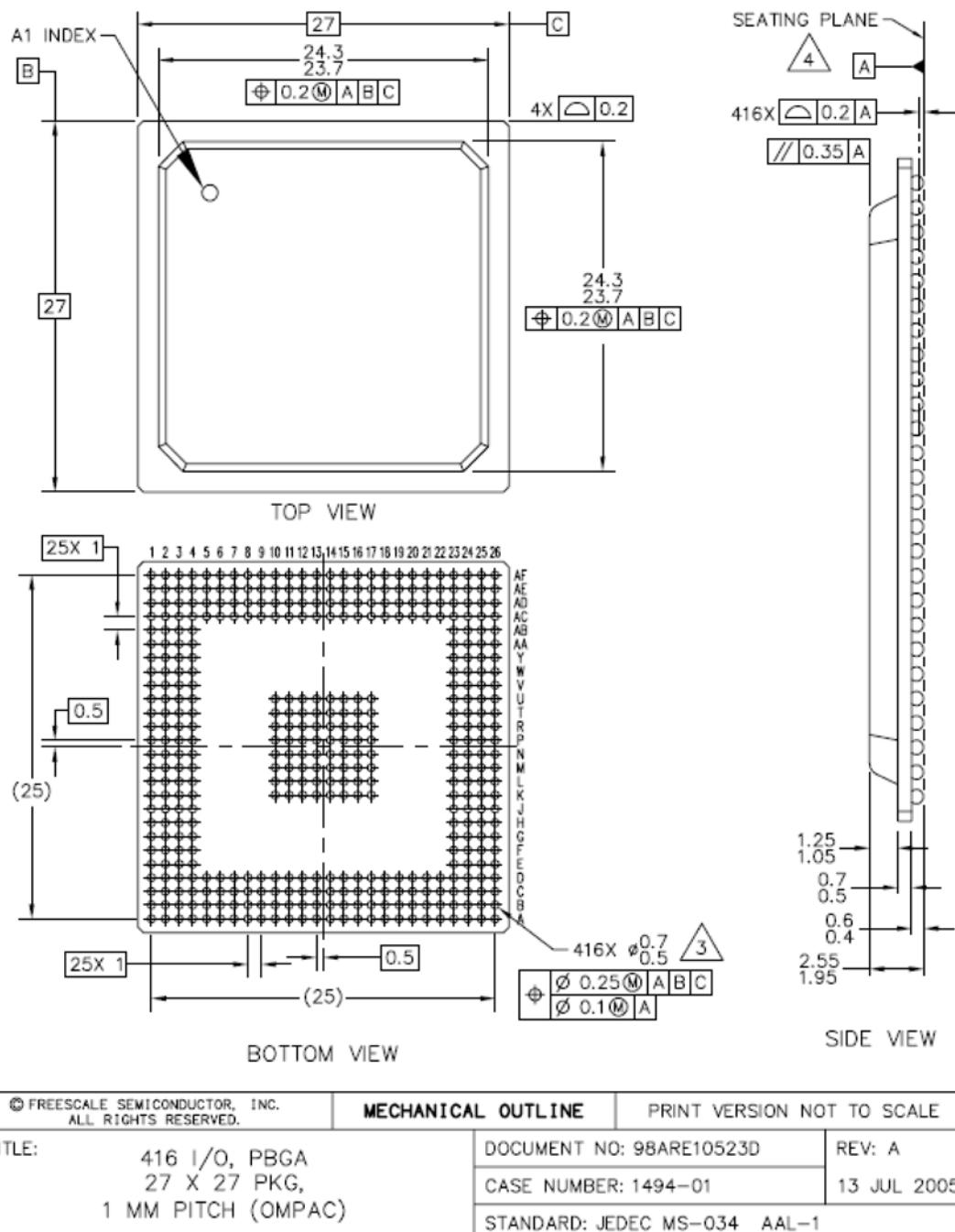


Figure 31. MPC5554 416 TEPBGA Package

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### NOTES:

1. ALL DIMENSIONS IN MILLIMETERS.
2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
3. MAXIMUM SOLDER BALL DIAMETER MEASURED PARALLEL TO DATUM A.
4. DATUM A, THE SEATING PLANE, IS DETERMINED BY THE SPHERICAL CROWNS OF THE SOLDER BALLS.

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TITLE: 416 I/O, PBGA 27 X 27 PKG, 1 MM PITCH (OMPAC)	DOCUMENT NO: 98ARE10523D CASE NUMBER: 1494-01 STANDARD: JEDEC MS-034 AAL-1	REV: A 13 JUL 2005

Figure 31. MPC5554 416 TEPBGA Package (continued)

## Revision History for the MPC5554 Data Sheet

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# 5 Revision History for the MPC5554 Data Sheet

The history of revisions made to this data sheet are described in this section.

## 5.1 Changes to Revision 2 in Revision 3

The substantive changes incorporated in MPC5554 Data Sheet Rev. 2.0 to produce Rev. 3.0 are listed in **Table 28**. The changes are listed in sequential page number order.

**Table 28. Changes Between Rev. 2.0 and 3.0**

Location	Description of Changes
Throughout:	Changed ' $T_A = T_L - T_H$ ' to ' $T_A = T_L$ to $T_H$ '.
Title page:	Changed the Revision number from 2 to 3. Changed the date. Made the same change in the lower left corner of the back page.
Section 1, "Overview"	<ul style="list-style-type: none"><li>Fourth paragraph, First sentence: Deleted 'of the MPC5500 family'; Second to last sentence: Deleted 'can'.</li><li>Fifth paragraph, First sentence: Replaced 'MPC5500 family' with 'MPC5554'; Last sentence: Replaced 'can be' with 'is'.</li><li>Sixth paragraph, First sentence: Replaced 'MPC5500 family' with 'MPC5554';</li><li>Second to last paragraph: Rewrote to read: The MCU has an on-chip enhanced queued dual analog-to-digital converter (eQADC). The 416 package has 40-channels.</li></ul>
Section 3.2.1, "General Notes for Specifications at Maximum Junction Temperature"	Updated the address of Semiconductor Equipment and Materials International 3081 Zanker Rd. San Jose, CA, 95134 (408) 943-6900
Section 3.7, "Power-Up/Down Sequencing"	Last paragraph: Changed the first sentence FROM . . . the voltage on the pins goes to high-impedance until . . . TO . . . the pins go to a high-impedance state until . . .
Section 3.7.3, "Power-Down Sequence (VRC33 Grounded)"	Last sentence: Changed from: 'This ensures that the digital 1.5 V logic, which is reset by the ORed POR only and can cause the 1.5 V supply to decrease below its specification, is reset properly.' To: 'This ensures that the digital 1.5 V logic, which is reset only by an ORed POR and can cause the 1.5 V supply to decrease less than its specification, resets correctly.'
Section 4.1, "MPC5554 416 PBGA Pinout"	Added the following NOTE before the 416 BGA Map:  <b>NOTE</b>  The MPC5500 devices are pin compatible for software portability and use the primary function names to label the pins in the BGA diagram. Although some devices do not support all the primary functions shown in the BGA diagram, the muxed and GPIO signals on those pins remain available. See the signals chapter in the device reference manual for the signal muxing.

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Table 28. Changes Between Rev. 2.0 and 3.0 (continued)

Location	Description of Changes
<b>Table 5 ESD Ratings:</b>	
	<p>Changed footnote 2 from:</p> <ul style="list-style-type: none"> <li>‘Device failure is defined as: ‘If after exposure to ESD pulses, the device no longer meets the device specification requirements. Complete DC parametric and functional testing will be performed per applicable device specification at room temperature followed by hot temperature, unless specified otherwise in the device specification.’</li> </ul> <p>to:</p> <ul style="list-style-type: none"> <li>Device failure is defined as: ‘If after exposure to ESD pulses, the device does not meet the device specification requirements, which includes the complete DC parametric and functional testing at room temperature and hot temperature.</li> </ul>
<b>Table 6 VCR/POR Electrical Specifications:</b>	
	<ul style="list-style-type: none"> <li>Added footnote 1 to specs 1, 2, and 3 that reads: The internal POR signals are <math>V_{POR15}</math>, <math>V_{POR33}</math>, and <math>V_{POR5}</math>. On power up, assert <math>\overline{RESET}</math> before the internal POR negates. <math>\overline{RESET}</math> must remain asserted until the power supplies are within the operating conditions as specified in <b>Table 9</b> DC Electrical Specifications. On power down, assert <math>\overline{RESET}</math> before any power supplies fall outside the operating conditions and until the internal POR asserts.</li> <li>Reformatted columns.</li> </ul>
<b>Table 9 DC Electrical Specifications:</b>	
	<ul style="list-style-type: none"> <li>Added footnote that reads: <math>V_{DDE2}</math> and <math>V_{DDE3}</math> are limited to 2.25–3.6 V only if <math>SIU\_ECCR[EBTS] = 0</math>; <math>V_{DDE2}</math> and <math>V_{DDE3}</math> have a range of 1.6–3.6 V if <math>SIU\_ECCR[EBTS] = 1</math>.</li> <li>Added (<math>T_A = T_L</math> to <math>T_H</math>) to the table title.</li> </ul>
<b>Table 14 Flash Program and Erase Specifications (<math>T_A = T_L</math> to <math>T_H</math>)</b>	
	<ul style="list-style-type: none"> <li>Footnote 1, Changed ‘Typical program and erase times assume nominal supply values and operation at 25 °C’ to ‘Typical program and erase times are calculated at 25 °C operating temperature using nominal supply values..’</li> </ul>
<b>Table 17 Pad AC Specifications (<math>V_{DDEH} = 5.0</math> V, <math>V_{DDE} = 1.8</math> V)</b>	
	<ul style="list-style-type: none"> <li>Footnote 1, changed ‘<math>V_{DDEH} = 4.5</math>–5.5,’ to ‘<math>V_{DDEH} = 4.5</math>–5.25,’</li> </ul>
<b>Table 19 Reset and Configuration Pin Timing:</b>	
	<ul style="list-style-type: none"> <li>Footnote 1: Removed <math>V_{DD} = 1.35</math>–1.65 V.</li> </ul>
<b>Table 20 JTAG Pin AC Electrical Characteristics</b>	
	<ul style="list-style-type: none"> <li>Footnote 1: Removed <math>V_{DD} = 1.35</math>–1.65 V, and <math>V_{DD33}</math> and <math>V_{DDSYN} = 3.0</math>–3.6 V.</li> </ul>
<b>Table 22 Bus Operation Timing:</b>	
	<ul style="list-style-type: none"> <li>External Bus Frequency in the table heading: Added footnote that reads: Speed is the nominal maximum frequency. Max speed is the maximum speed allowed including frequency modulation (FM). 82 MHz parts allow for 80 MHz system clock + 2% FM; 114 MHz parts allow for 112 MHz system clock + 2% FM; and 132 MHz parts allow for 128 MHz system clock + 2% FM.</li> <li>Specifications 5, 6, 7, and 8: Reordered the EBI signals within each specification.</li> <li>Specifications 7 and 8: Removed EBI signals <math>\overline{BDIP}</math>, <math>\overline{OE}</math>, <math>TSIZ[0:1]</math>, <math>WE/\overline{BE}[0:3]</math>.</li> <li>Footnote 1: Removed <math>V_{DD} = 1.35</math>–1.65 V, and <math>V_{DD33}</math> and <math>V_{DDSYN} = 3.0</math>–3.6 V.</li> <li>Footnote 8: Changed EBTS to <math>SIU\_ECCR[EBTS]</math>.</li> </ul>
<b>Table 23 External Interrupt Timing (IRQ Signals)</b>	
	<ul style="list-style-type: none"> <li>Footnote 1: Removed <math>V_{DD} = 1.35</math>–1.65 V; changed <math>V_{DDEH} = 3.0</math>–5.5 V to <math>V_{DDEH} = 3.0</math>–5.25 V.</li> </ul>
<b>Table 24 eTPU Timing</b>	
	<ul style="list-style-type: none"> <li>Footnote 1: Changed <math>V_{DDEH} = 3.0</math>–5.5 V to <math>V_{DDEH} = 3.0</math>–5.25 V.</li> </ul>
<b>Table 25 eMIOS Timing</b>	
	<ul style="list-style-type: none"> <li>Footnote 1: Changed <math>V_{DDEH} = 3.0</math>–5.5 V to <math>V_{DDEH} = 3.0</math>–5.25 V.</li> </ul>

## Revision History for the MPC5554 Data Sheet

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**Table 28. Changes Between Rev. 2.0 and 3.0 (continued)**

Location	Description of Changes
<a href="#">Table 26</a> DSPI Timing:	<ul style="list-style-type: none"><li>Footnote 1, changed '<math>V_{DDEH} = 3.0\text{--}5.5\text{ V}</math>;' to '<math>V_{DDEH} = 3.0\text{--}5.25\text{ V}</math>'</li><li>Table Title: Added footnote that reads: Speed is the nominal maximum frequency. Max speed is the maximum speed allowed including frequency modulation (FM). 82 MHz parts allow for 80 MHz system clock + 2% FM; 114 MHz parts allow for 112 MHz system clock + 2% FM; and 132 MHz parts allow for 128 MHz system clock + 2% FM.</li><li>Spec 1: SCK cycle time; Changed to 80 MHz minimum column from 25 to 24.4; 112 MHz minimum column from 17.9 to 17.5; 112 MHz maximum column from 2.0 to 2.1.</li></ul>

[Table 27](#) EQADC SSI Timing Characteristics

<ul style="list-style-type: none"><li>Footnote 1: Changed <math>V_{DDEH} = 3.0\text{--}5.5\text{ V}</math> to <math>V_{DDEH} = 3.0\text{--}5.25\text{ V}</math>.</li></ul>
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